

Supplementary Information

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Methods.

^1H , ^{13}C , and ^{19}F NMR spectra were recorded on a Varian AS400 or Agilent DD2 500 MHz apparatus in deuterated solvents. Chemical shifts were reported as δ values (ppm) relative to the residual protic solvent. The number-average (M_n) and weight average (M_w) molecular weights were determined by size exclusion chromatography (SEC) using a Malvern HT-GPC equipped with an RI detector. The flow rate was fixed at 0.75 mL/min using 1,2,4-trichlorobenzene (TCB) (with 0.0125% BHT w/v) as the eluent. The temperature of the system was set to 110 °C. All the samples were prepared at concentrations of nominally 0.50 mg/mL in TCB. The sample vials were held at 110 °C with stirring for 1 h for complete dissolution. The calibration method used to generate the reported data was the classical polystyrene method using polystyrene standards which were dissolved in TCB. UV-vis absorption spectra were taken using a Thermo Scientific Genesys 10S spectrophotometer using 1 cm path-length quartz cells. For solid-state measurements, polymer solution was spin-cast on glass plates. Optical bandgaps were calculated from the onset of the absorption band. Cyclic voltammograms were recorded on a Solartron 1287 potentiostat using platinum wires as working electrode and counter electrode at a scan rate of 50 mV/s. The reference electrode was Ag/Ag⁺ (0.01 M AgNO₃ in acetonitrile), and the electrolyte was a solution of 0.1 M tetrabutylammonium hexafluorophosphate (Bu₄NPF₆) in dry acetonitrile. In these conditions, the oxidation potential of ferrocene was 0.09 V versus Ag/Ag⁺, whereas the oxidation potential of ferrocene was 0.41 V versus saturated calomel electrode (SCE). The HOMO and LUMO energy levels were determined from the oxidation and reduction onsets (where the current differs from the baseline) assuming that SCE electrode is -4.71 eV from vacuum, as reported in the literature.⁶⁵ Thermogravimetric analysis (TGA) measurements were carried out with a Mettler Toledo TGA SDTA 851e apparatus at a heating rate of 10 °C/min under a nitrogen atmosphere. The temperature of degradation (T_d) corresponds to a 5% weight loss. Differential scanning calorimetry (DSC) analyses were performed on a PerkinElmer DSC-7 instrument calibrated with ultrapure indium at a scanning rate of 10 °C/min under a nitrogen flow. X-ray diffraction (XRD) was conducted on a Bruker D8 Discover powder diffractometer with a standard Bragg-Brentano geometry and a microfocus X-ray source (IuS) (Cu-K-alpha, $\lambda = 0.15418$ nm) was used to collect the XRD patterns of the polymer thin films on dodecyltrichlorosilane (DDTS)-modified SiO₂/Si substrates.

Materials.

2,3-Dibromothiophene and N-fluorobenzenesulfonimide (NFSI) were purchased from Combiblocks. NFSI was recrystallized in diethyl ether prior to use. *n*-Octyldimethylchlorosilane was purchased from Gelest Inc.

Polymers

Optimisation table

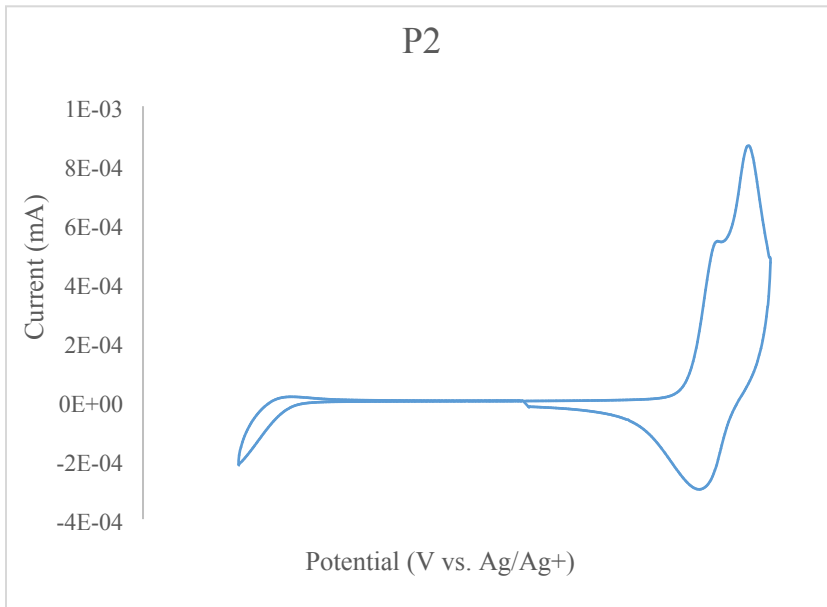
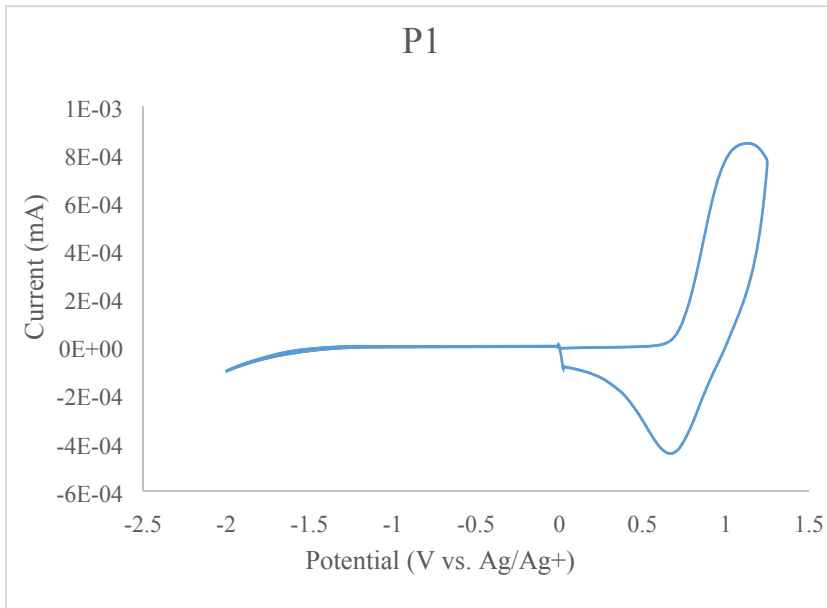
Entry	Poly.	Cat.	Ligand	base	solvent	conditions	Yield	Mn (g/mol)	Ip
1	P2	Herrmann's	P(<i>o</i> MeO-Ph) ₃	Cs ₂ CO ₃	Tol., 0.1M	120°C, 18h	87%	9727	1.71
2	P3	Herrmann's	P(<i>o</i> MeO-Ph) ₃	Cs ₂ CO ₃	Tol., 0.1M	120°C, 18h	88%	13142	1.65
3 ^a	P2	Pd ₂ dba ₃	P(<i>o</i> MeO-Ph) ₃	Cs ₂ CO ₃	Tol., 0.1M	120°C, 18h	-	-	-
4 ^a	P2	Pd(OAc) ₂	-	Cs ₂ CO ₃	DMAc, 0.1M	120°C, 18h	75%	-	-
5	P2	Pd(OAc) ₂	-	Cs ₂ CO ₃	DMAc/Tol., 0.1M	120°C, 18h	74%	22888	1.47
6	P3	Pd(OAc) ₂	-	Cs ₂ CO ₃	DMAc/Tol., 0.1M	120°C, 18h	82%	21905	1.75

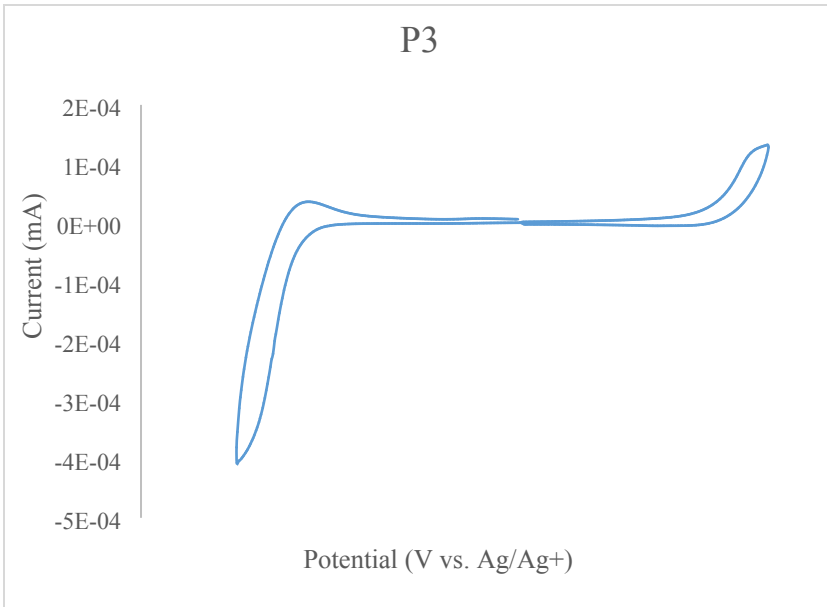
^a only oligomerization occurs, no GPC was realised.

General DHAP procedure

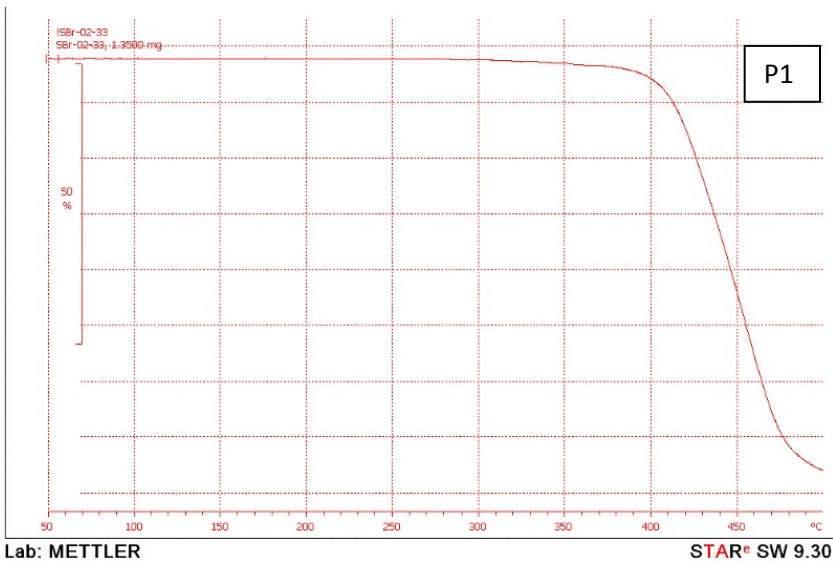
Alkylated fDT-DPP (1 eq.), fluorinated comonomer (1 eq.), palladium acetate (2% mol), Cs₂CO₃ (3 eq.), and pivalic acid (1 eq.) were put in a microwave vial with a magnetic stirring bar. The vial was sealed with a cap and then purged with nitrogen 3 times. Degassed and anhydrous toluene was added (C = 0.2 mol/L), and the microwave vial was heated at 120 °C. After heating for 18 h, the mixture was diluted in CHCl₃, poured in methanol and the solid was recovered by filtration using a 0.45 µm nylon filter. The polymer was washed using a Soxhlet apparatus with methanol, acetone, hexanes and then chloroform. The chloroform fraction was reduced to 5–10 mL and then poured in methanol. The polymer was recovered by filtration over a 0.45 µm nylon filter and dry under vacuum.

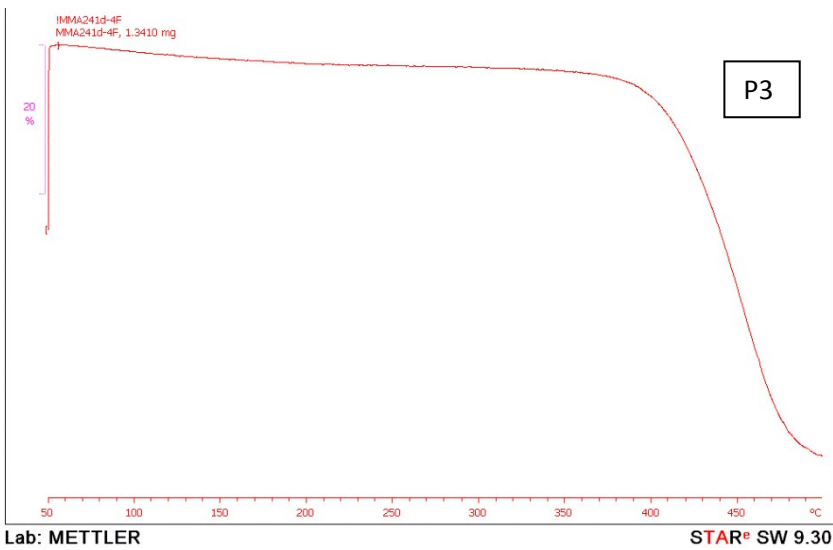
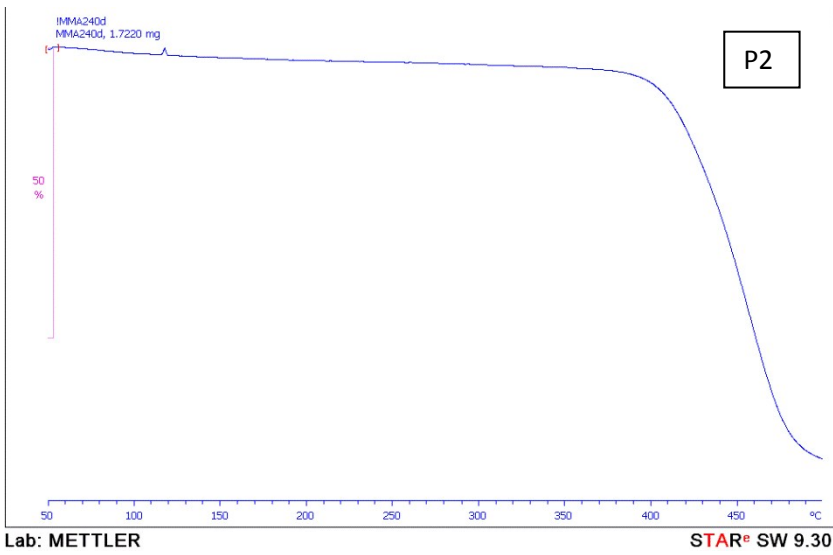
Cyclic Voltammetry curves



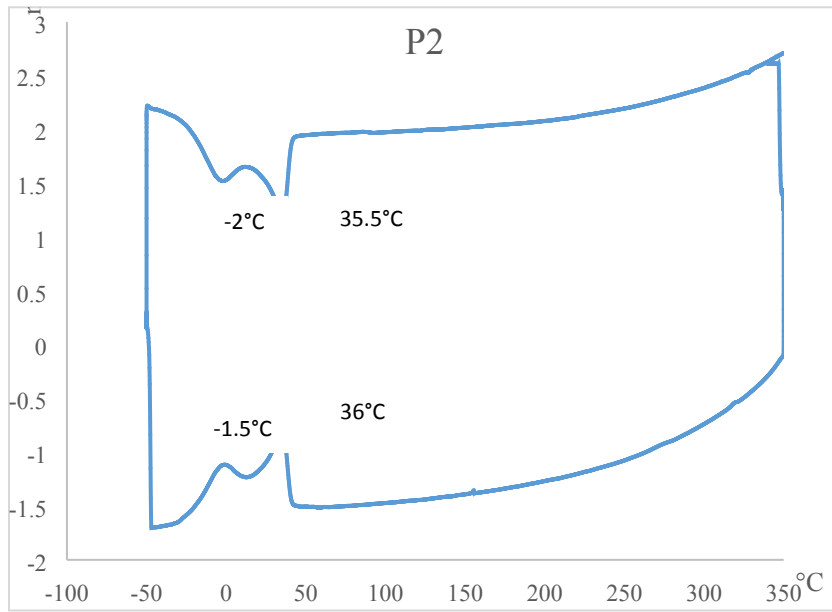
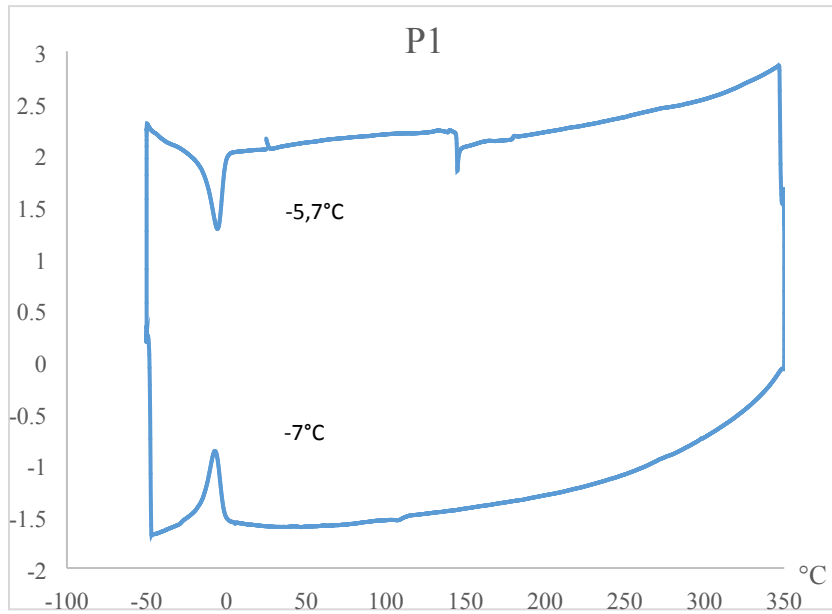


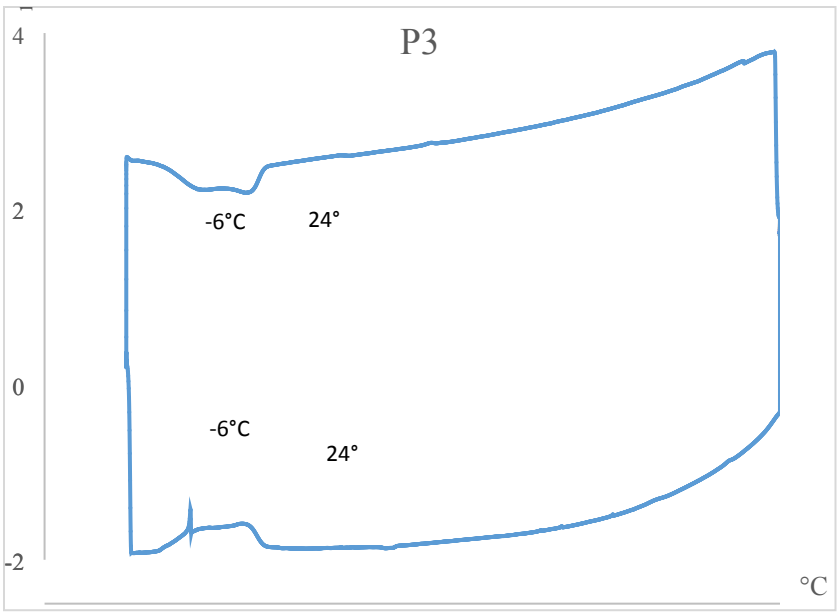
TGA curves





DSC curves

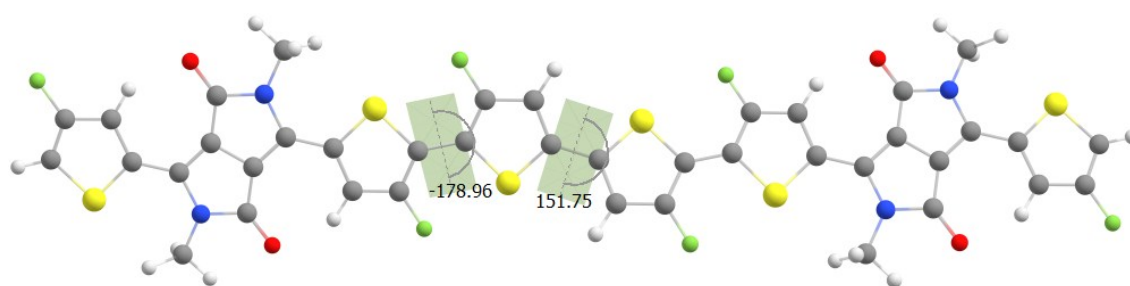




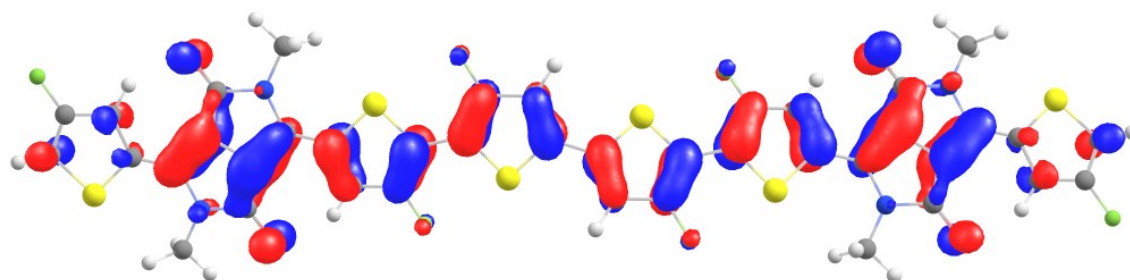
DFT calculation

Density-functional theory (DFT) and time-dependent DFT (TDDFT) calculations were realized with wB97XD functional¹ and the 6-31+G(d,p) basis set as implemented by Gaussian 16, version.C.01. software package².

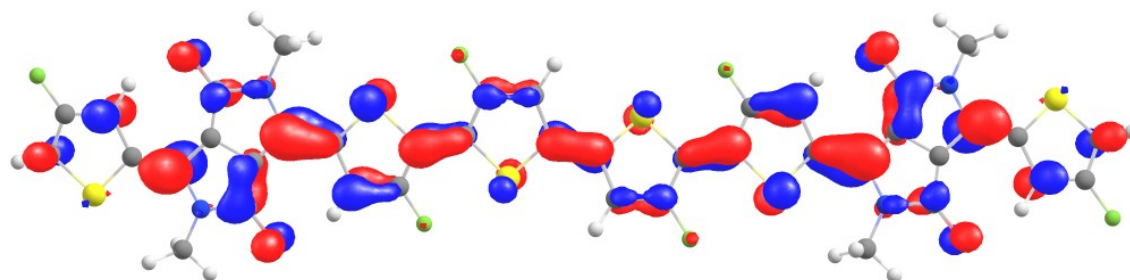
fDT-DPP-2F2Th



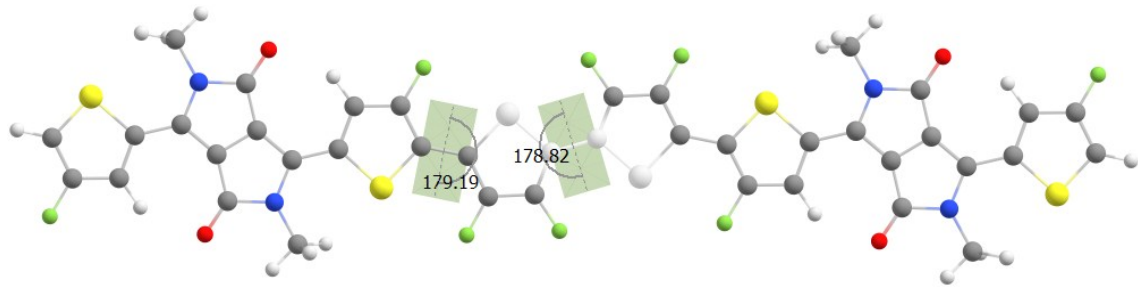
HOMO



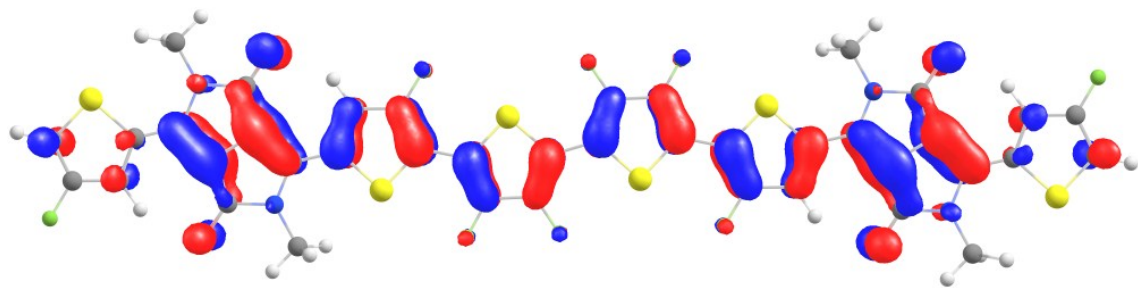
LUMO



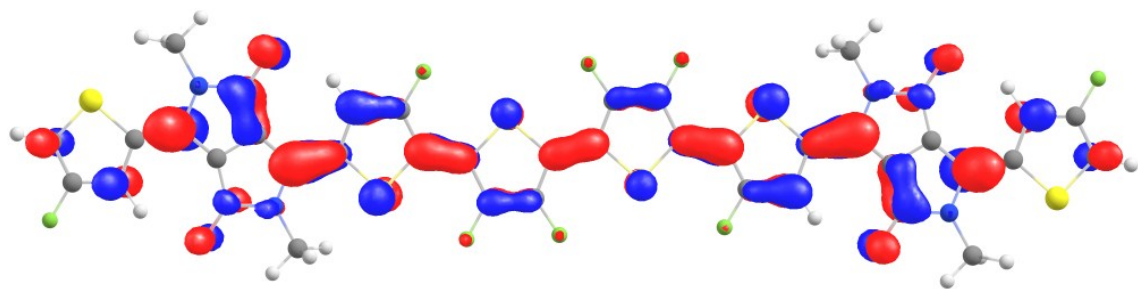
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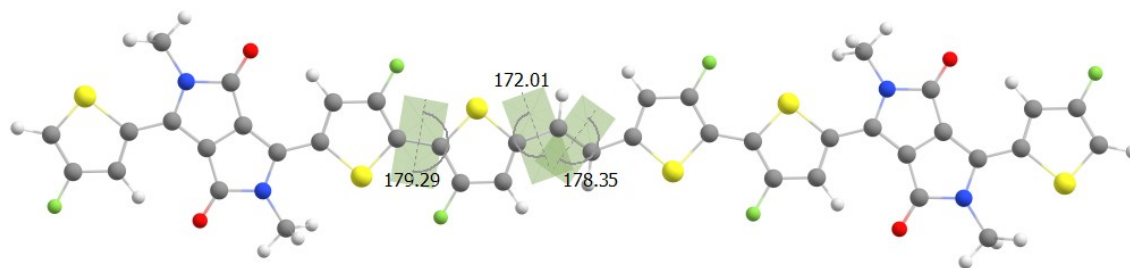
HOMO



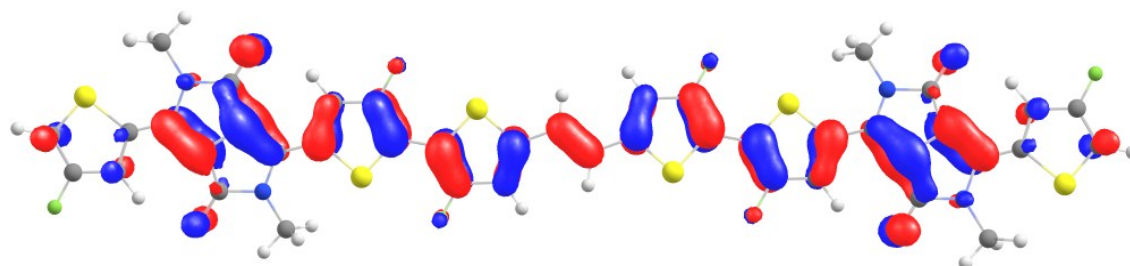
LUMO



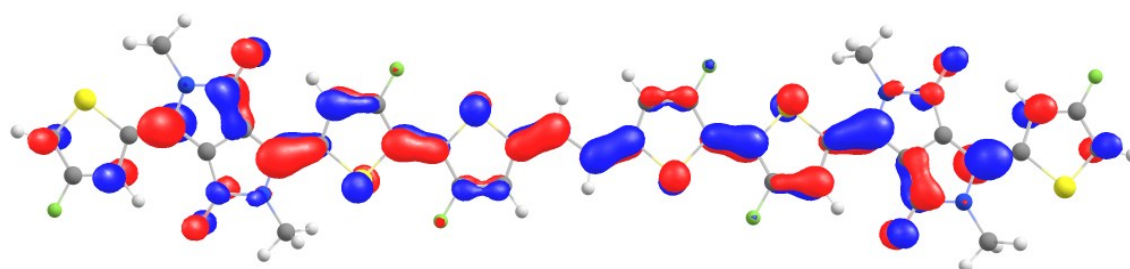
fDT-DPP-2FV2Th



HOMO



LUMO



1. Chai, J. D.; Head-Gordon, M. Long-Range Corrected Hybrid Density Functionals with Damped Atom-Atom Dispersion Corrections. *Phys. Chem. Chem. Phys.* 2008, 10, 6615–6620.

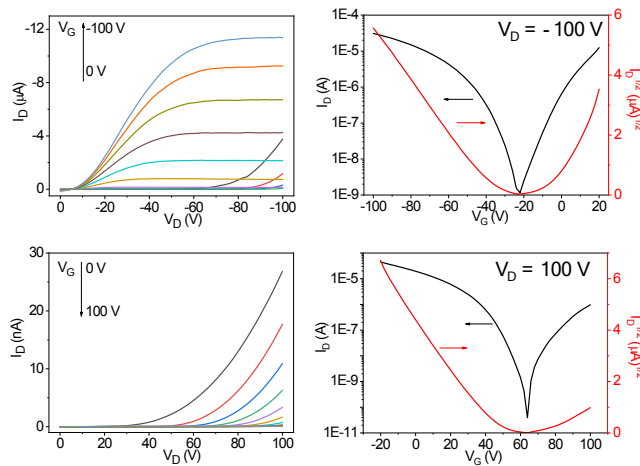
2. M. J. Frisch, G. W. Trucks, H. B. Schlegel, G. E. Scuseria, M. A. Robb, J. R. Cheeseman, G. Scalmani, V. Barone, G. A. Petersson, H. Nakatsuji, X. Li, M. Caricato, A. V. Marenich, J. Bloino, B. G. Janesko, R. Gomperts, B. Mennucci, H. P. Hratchian, J. V. Ortiz, A. F. Izmaylov, J. L. Sonnenberg, D. Williams-Young, F. Ding, F. Lipparini, F. Egidi, J. Goings, B. Peng, A. Petrone, T. Henderson, D. Ranasinghe, V. G. Zakrzewski, J. Gao, N. Rega, G. Zheng, W. Liang, M. Hada, M. Ehara, K. Toyota, R. Fukuda, J. Hasegawa, M. Ishida, T. Nakajima, Y. Honda, O. Kitao, H. Nakai, T. Vreven, K. Throssell, J. A. Montgomery, Jr., J. E. Peralta, F. Ogliaro, M. J. Bearpark, J. J. Heyd, E. N. Brothers, K. N. Kudin, V. N. Staroverov, T. A. Keith, R. Kobayashi, J. Normand, K. Raghavachari, A. P. Rendell, J. C. Burant, S. S. Iyengar, J. Tomasi, M. Cossi, J. M. Millam, M. Klene, C. Adamo, R. Cammi, J. W. Ochterski, R. L. Martin, K. Morokuma, O. Farkas, J. B. Foresman, and D. J. Fox, Gaussian, Inc., Wallingford CT, 2016.

OFET fabrication

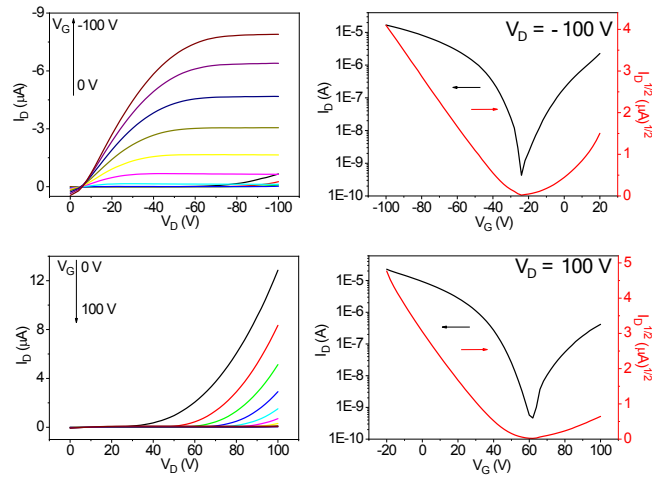
A bottom-contact, bottom-gate OFET configuration was used. Heavily p-doped Si wafer functioned as the gate electrode and a thermally grown SiO₂ layer (~300 nm) with a capacitance of ~10 nF/cm² on top of the Si layer was used as the insulating dielectric. Au source, drain and gate electrodes were pre-deposited on the SiO₂ layer with photolithography method and then modified with octadecanethiol. The substrates were cleaned with DI water, acetone, and isopropanol in an ultrasonic bath, followed by O₂ plasma. Subsequently, the substrates were immersed in a dodecyltrichlorosilane (DDTS) solution in toluene (10 mg/mL) at room temperature for 20 min. After washed with toluene, the substrates were dried under a nitrogen flow. A polymer solution in chloroform (concentration: **P1** and **P2**: 5 mg/mL; **P3**: 2-3 mg/mL) was spin coated on the substrate at 3000 rpm for 60 s to give a film, which was subjected to thermal annealing at different temperature for 20 min in glove box. The channel length (L) and width (W) was 30 and 1000 μm, respectively. The devices were characterized in air using an Agilent B2912A Semiconductor Analyzer. The carrier mobility in the saturated regime, μ_{sat} , was calculated according to the equation of $I_{\text{DS}} = C_i \mu_{\text{sat}} (W/2L)(V_G - V_T)^2$, where I_{DS} is the drain current, C_i is the capacitance of the gate dielectric, and V_G and V_T are the gate voltage and threshold voltage, respectively. V_T of the devices was determined from extrapolation of the linear fit of the $(I_{\text{DS}})^{1/2}$ versus V_G curve in the saturation regime at $I_{\text{DS}} = 0$.

Output and transfer curves of OFETs

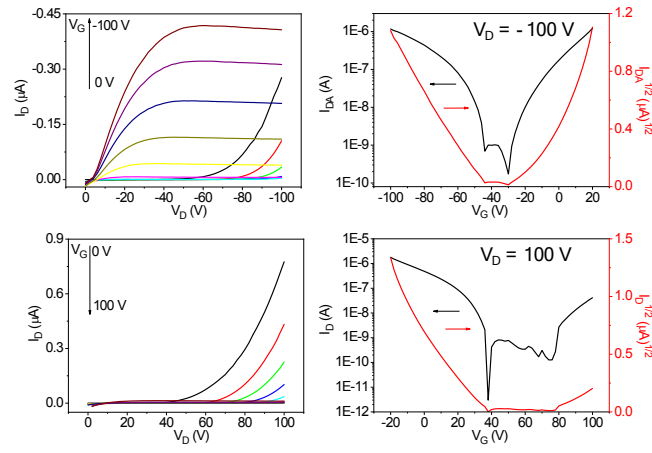
P1



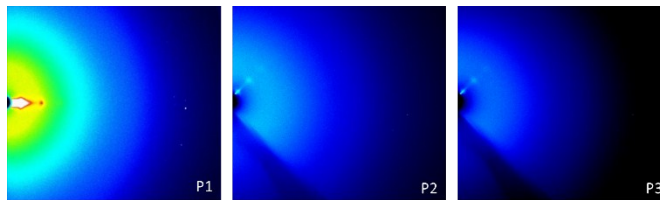
P2



P3



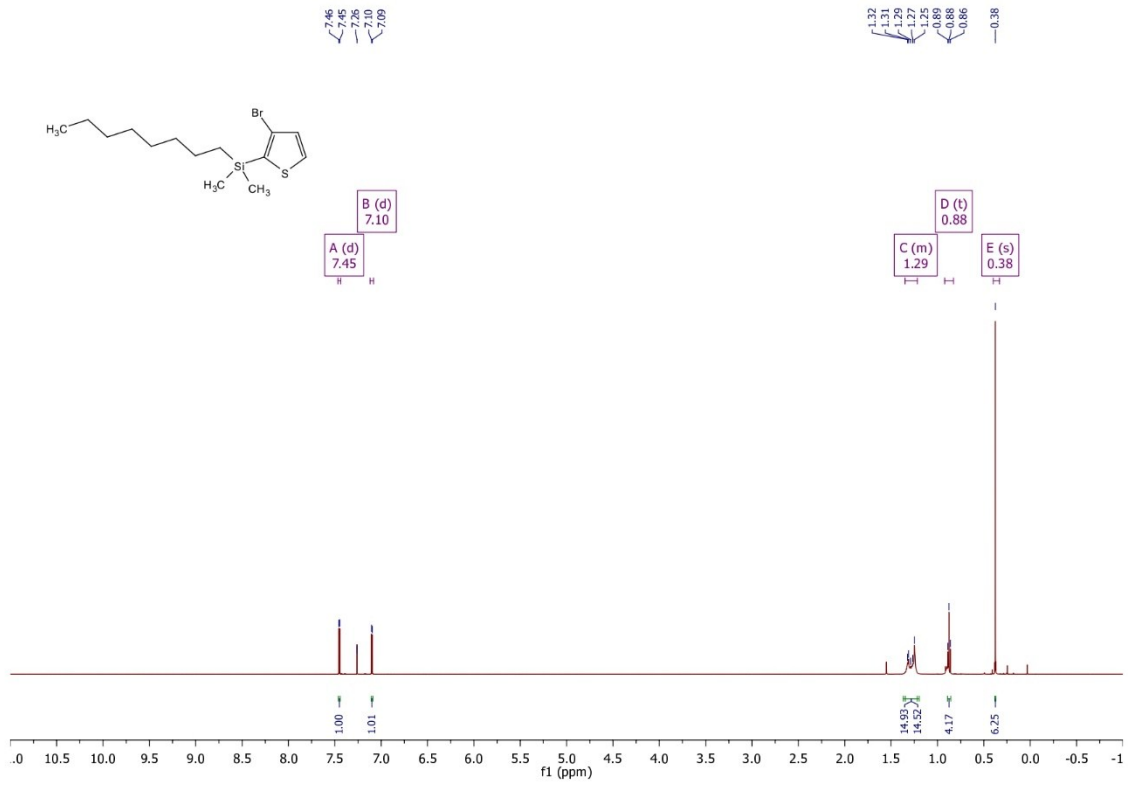
X-ray diffraction



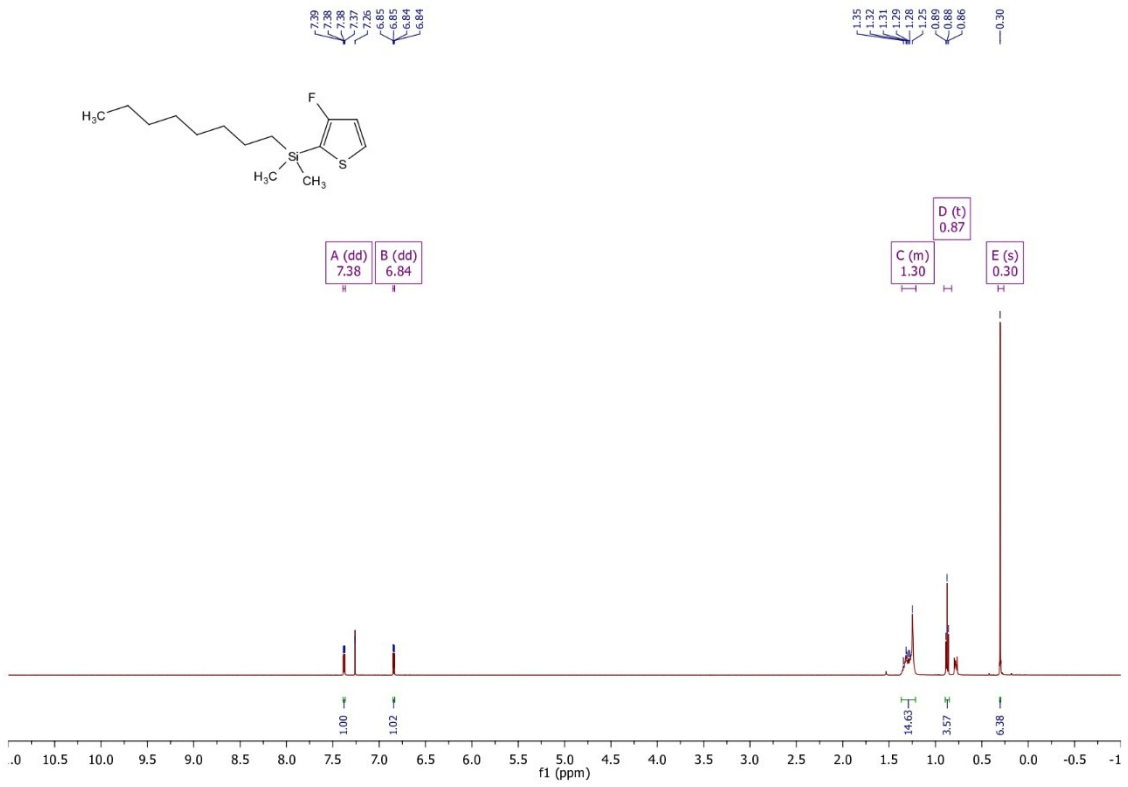
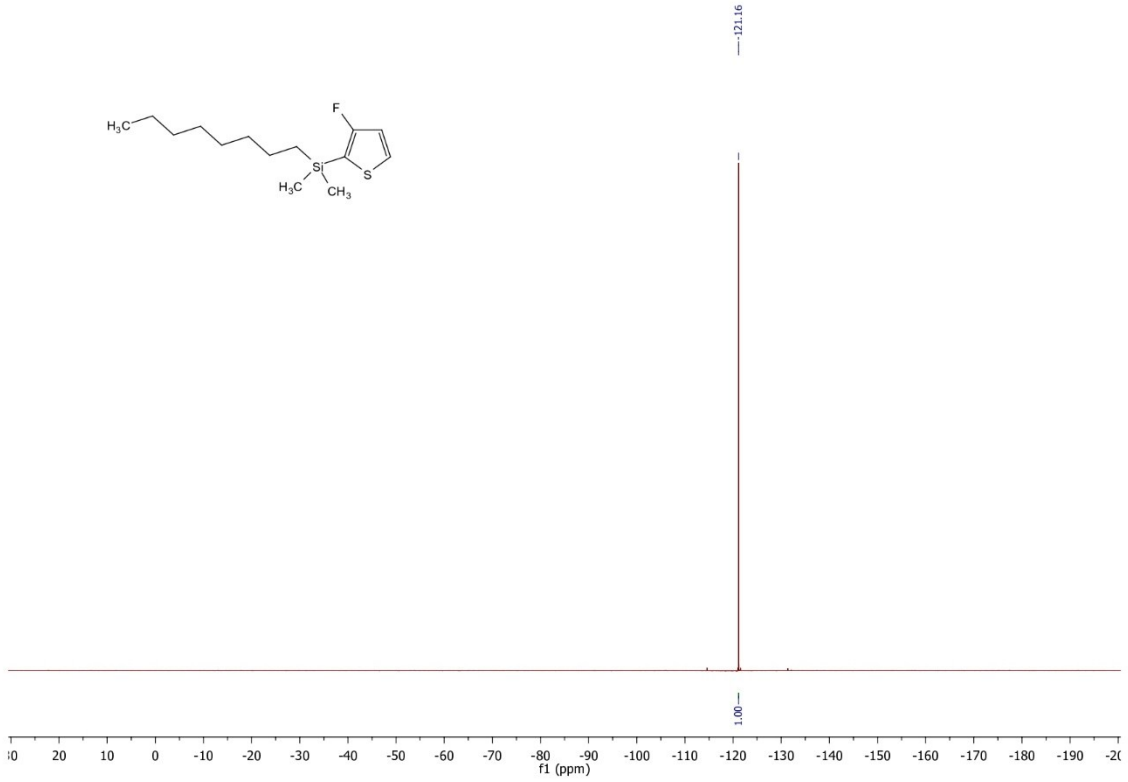
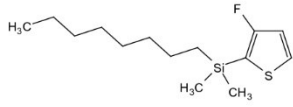
two-dimensional grazing-incidence X-ray diffraction (2D-GIXD) for P1, P2 and P3

NMR spectrum

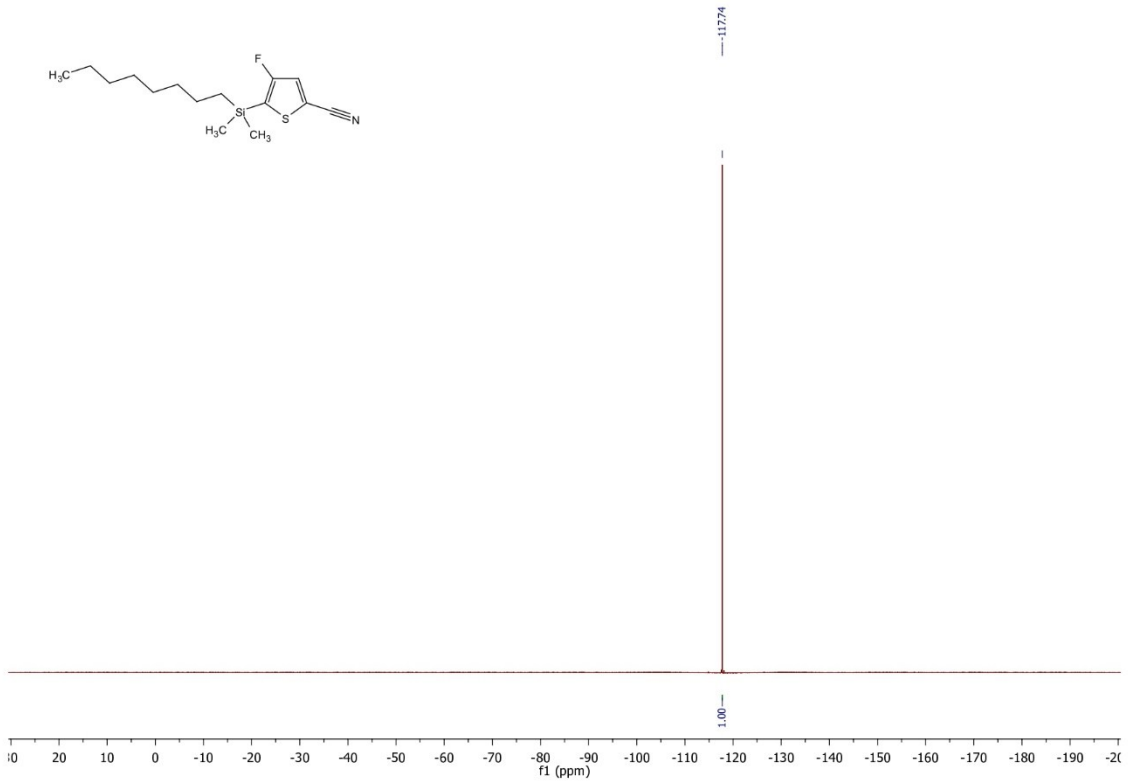
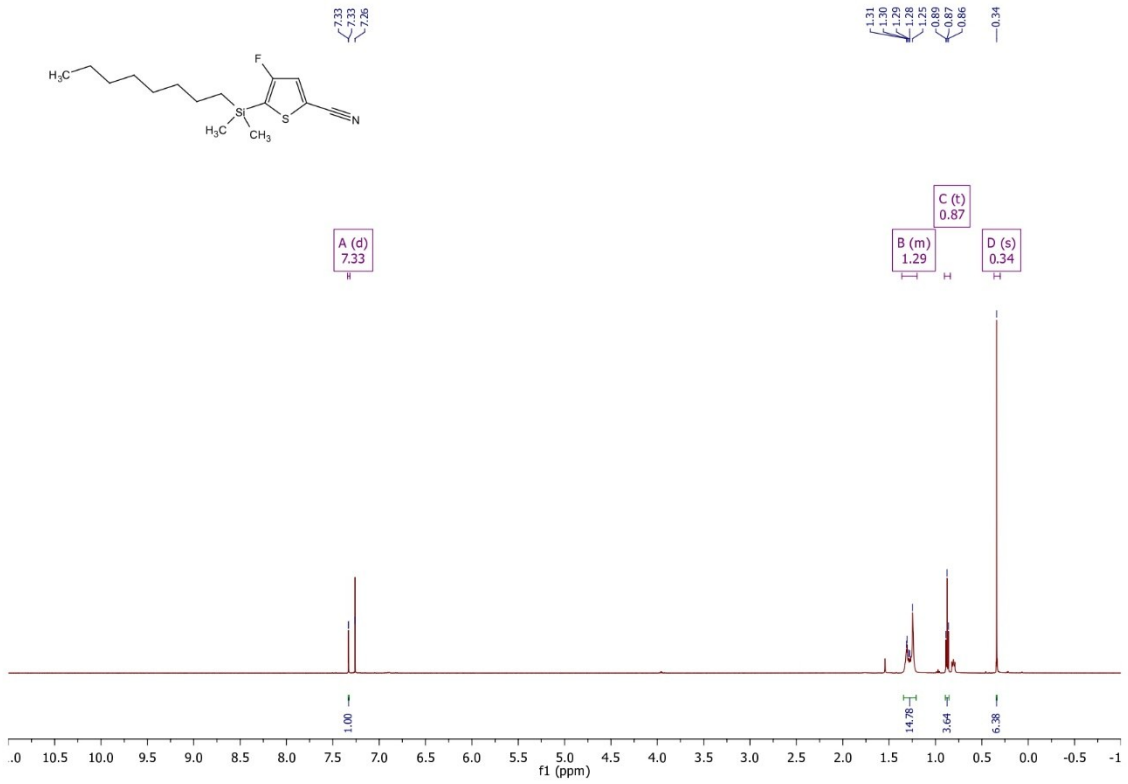
3-bromo-2-(dimethyloctylsilyl)thiophene (5)



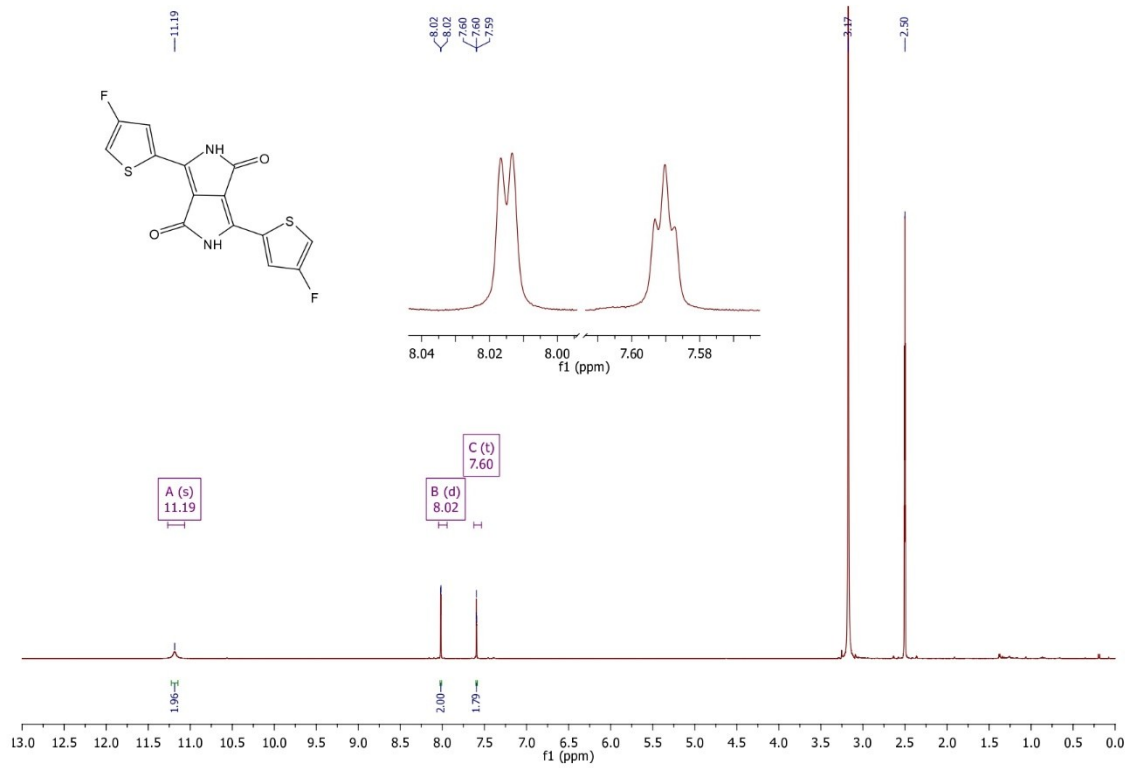
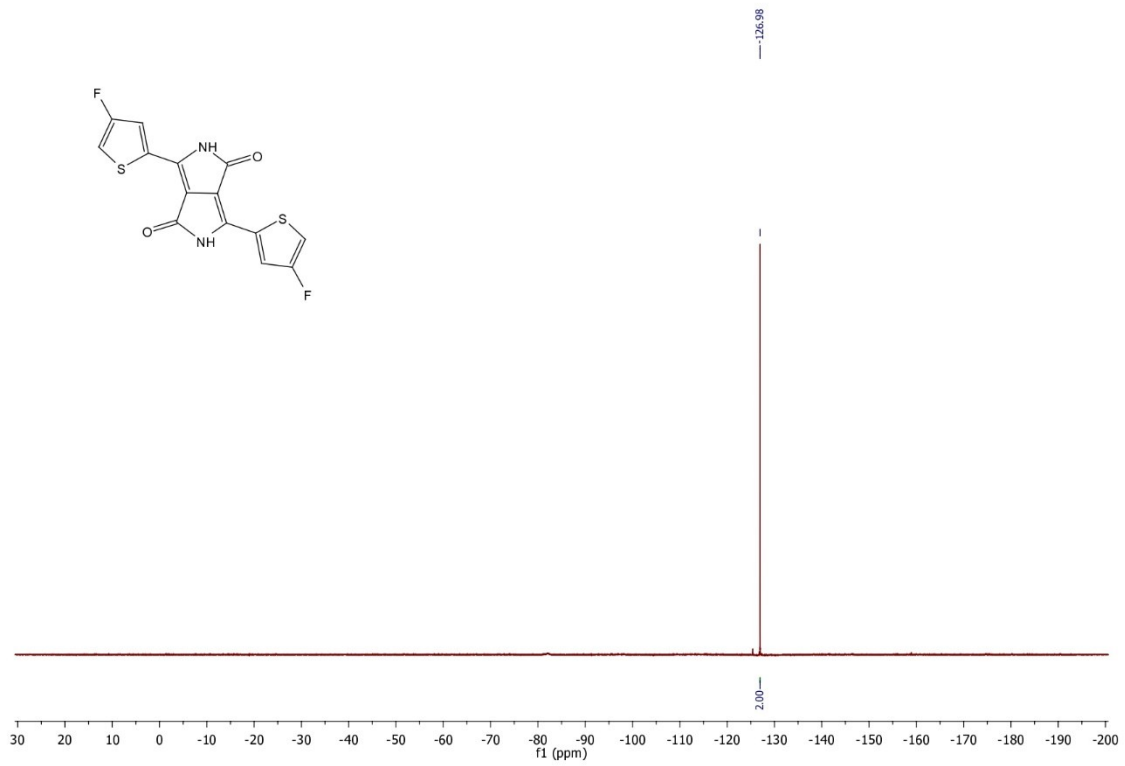
3-fluoro-2-(dimethyloctylsilyl)thiophene (6)



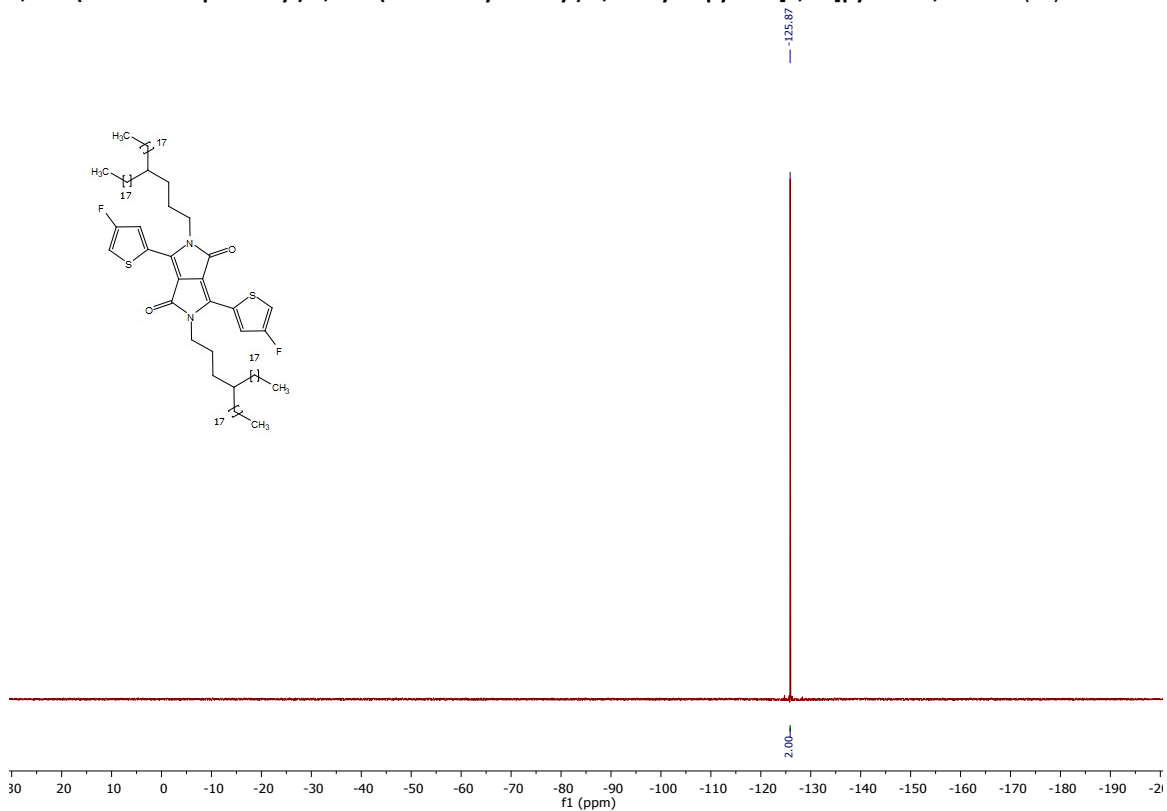
4-fluoro-5-(dimethyloctylsilylyl)-2-thiophenecarbonitrile (7)

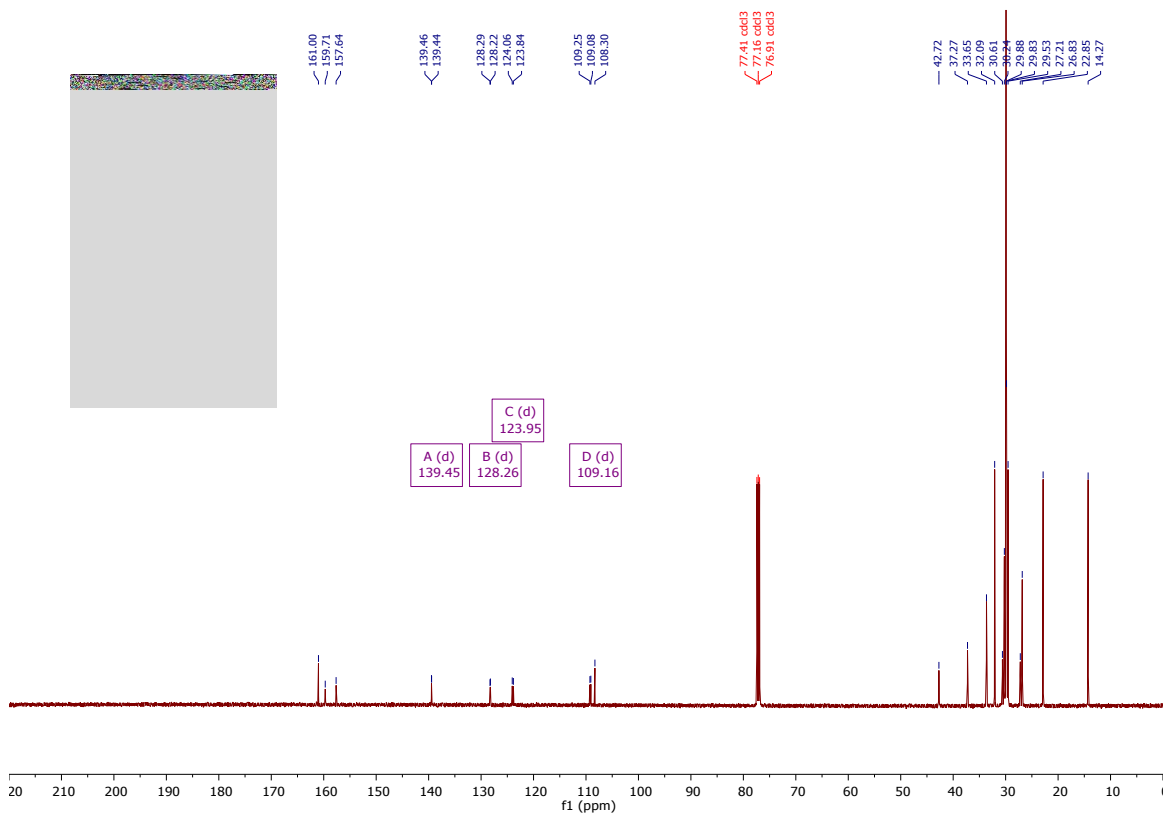
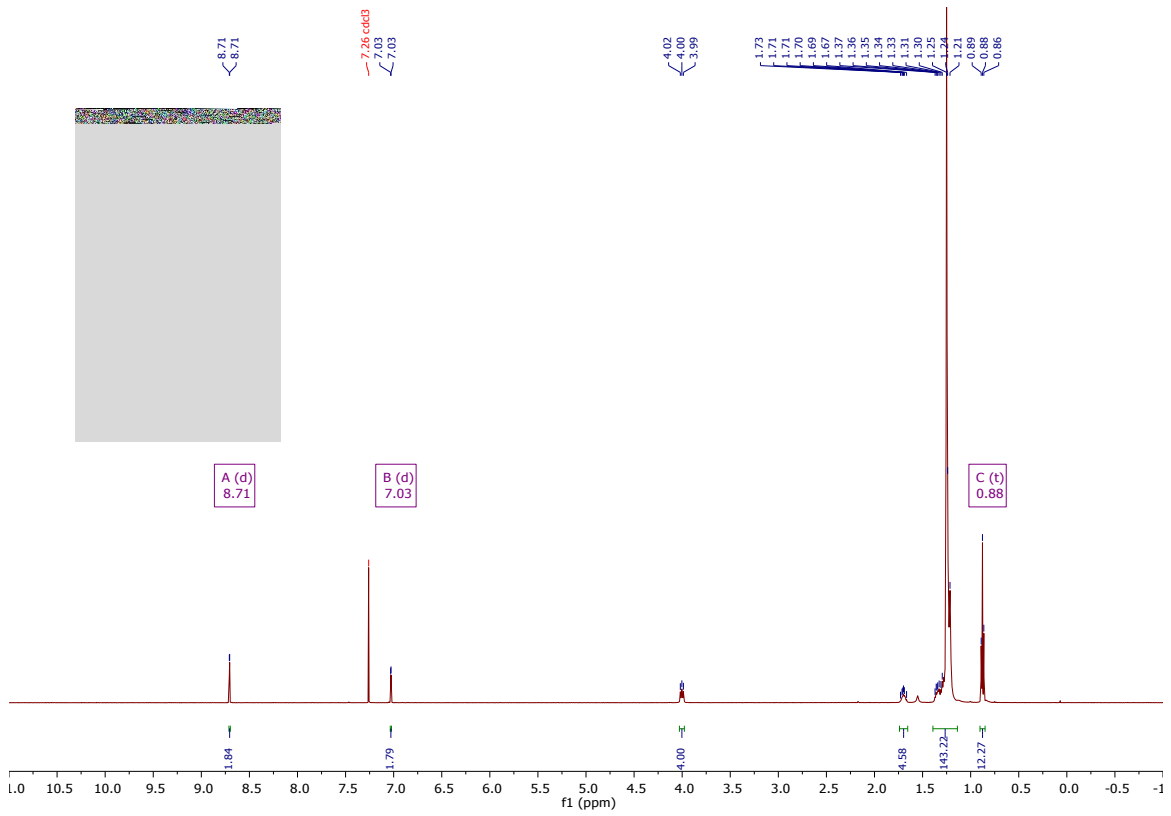


3,6-bis(4-fluorothiophen-2-yl)-2,5-dihydropyrrolo[3,4-c]pyrrole-1,4-dione (fDT-DPP)

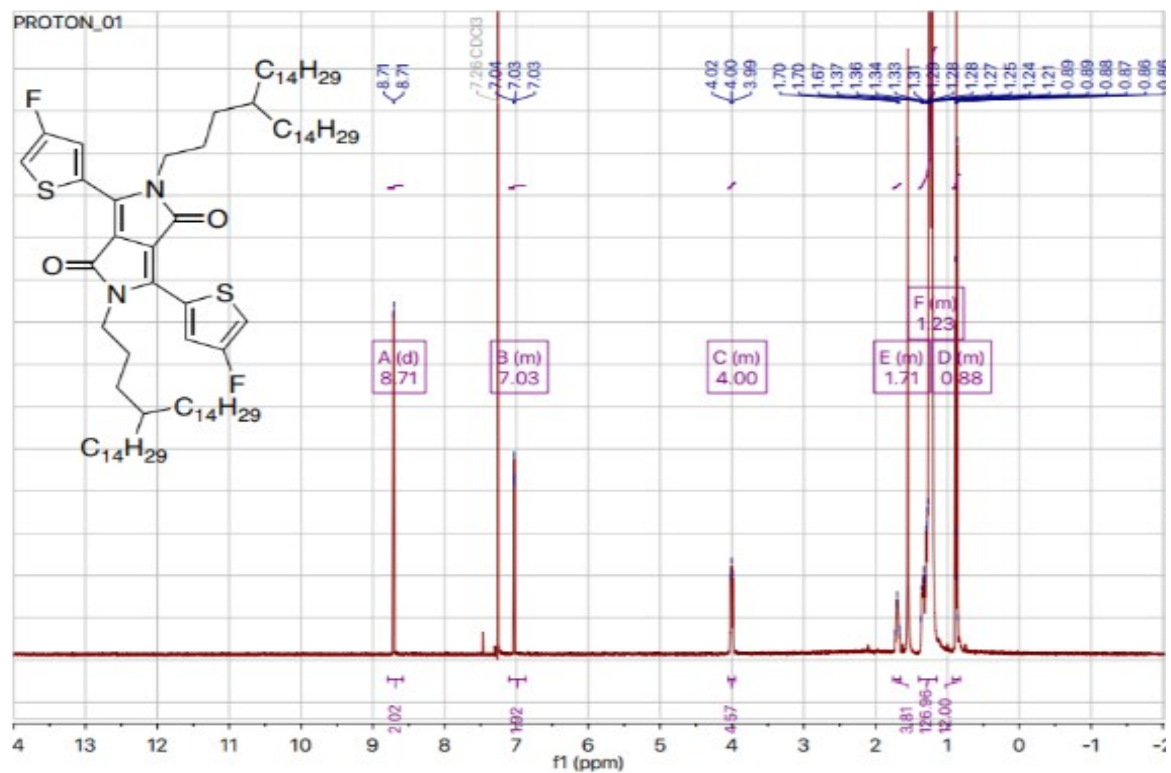


3,6-bis(4-fluorothiophen-2-yl)-2,5-bis(4-octadecyldocosyl)-2,5-dihydropyrrolo[3,4-c]pyrrole-1,4-dione (8a)

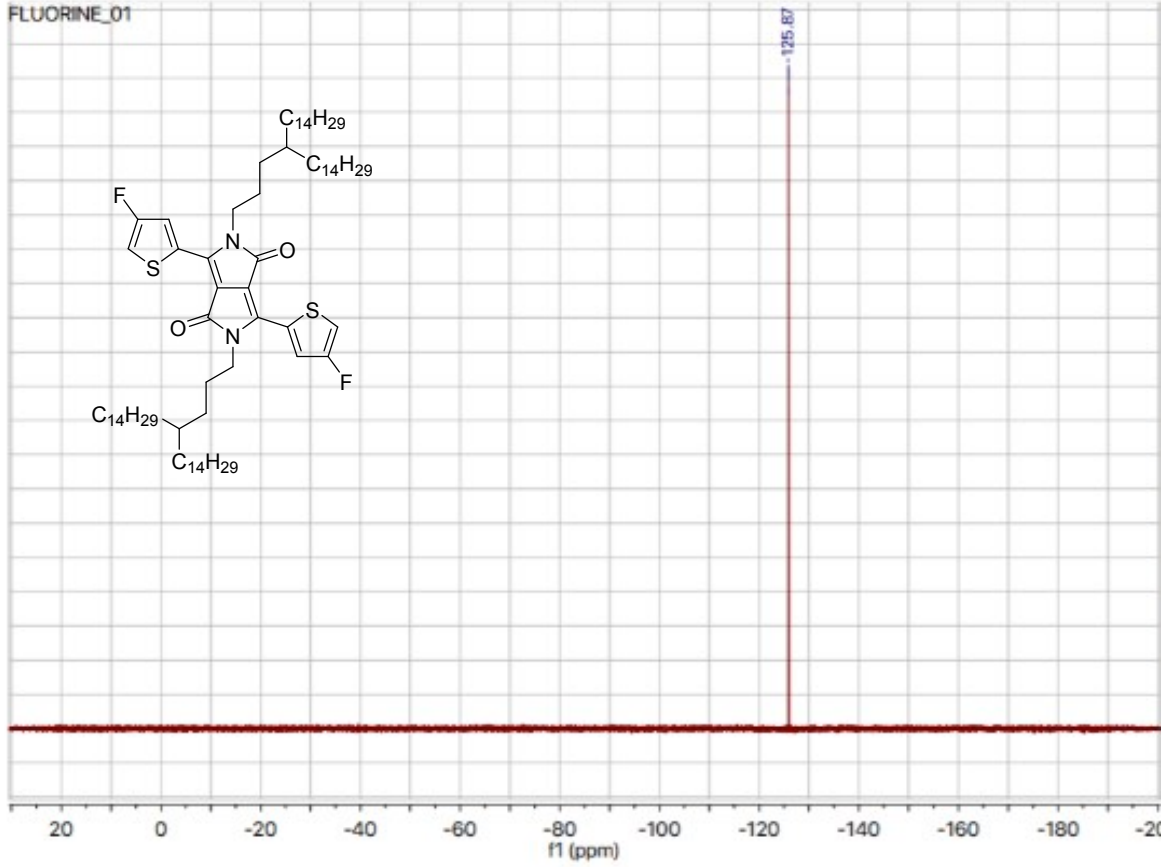




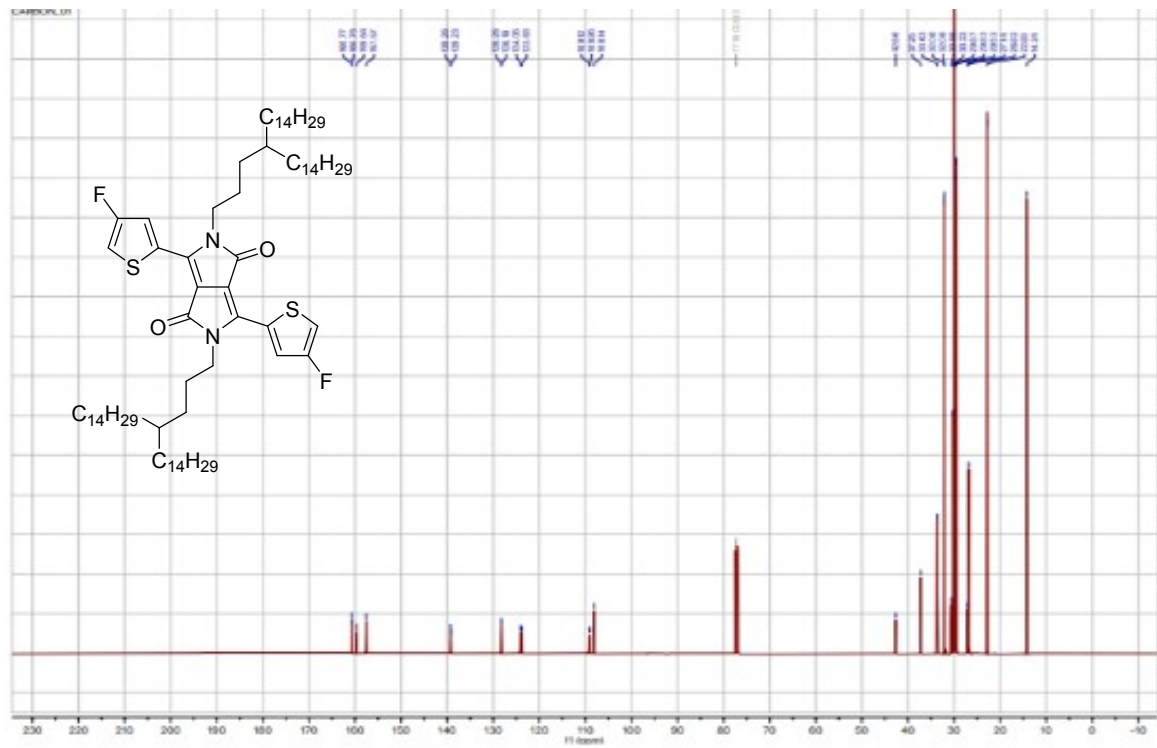
3,6-bis(4-fluorothiophen-2-yl)-2,5-bis(4-tetradecyloctadecyl)-2,5-dihydropyrrolo[3,4-c]pyrrole-1,4-dione (8b)



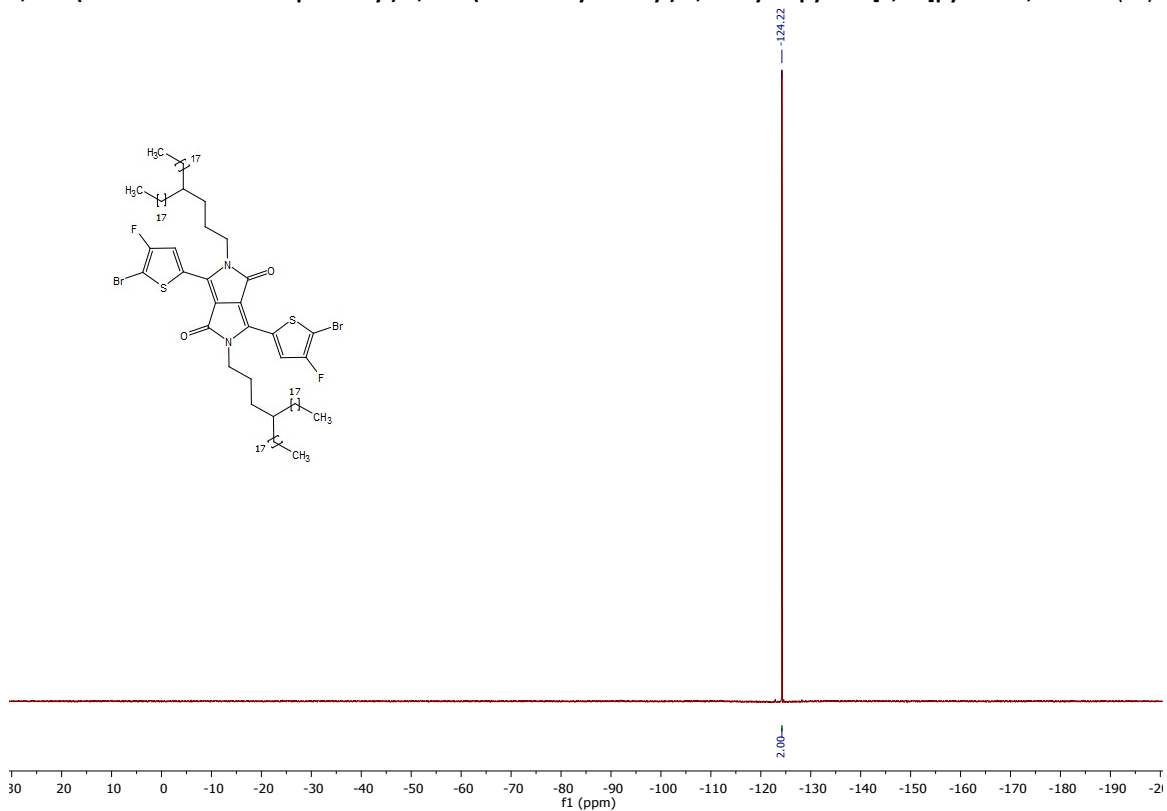
FLUORINE_01

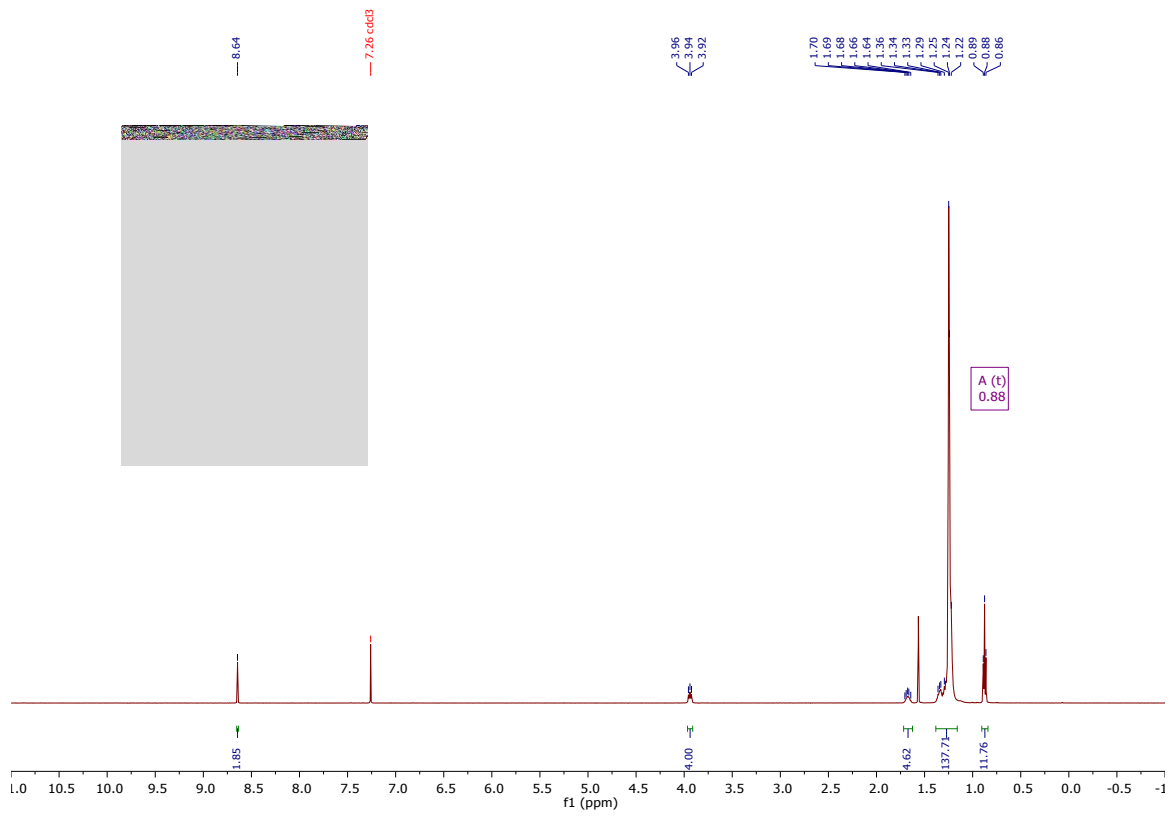


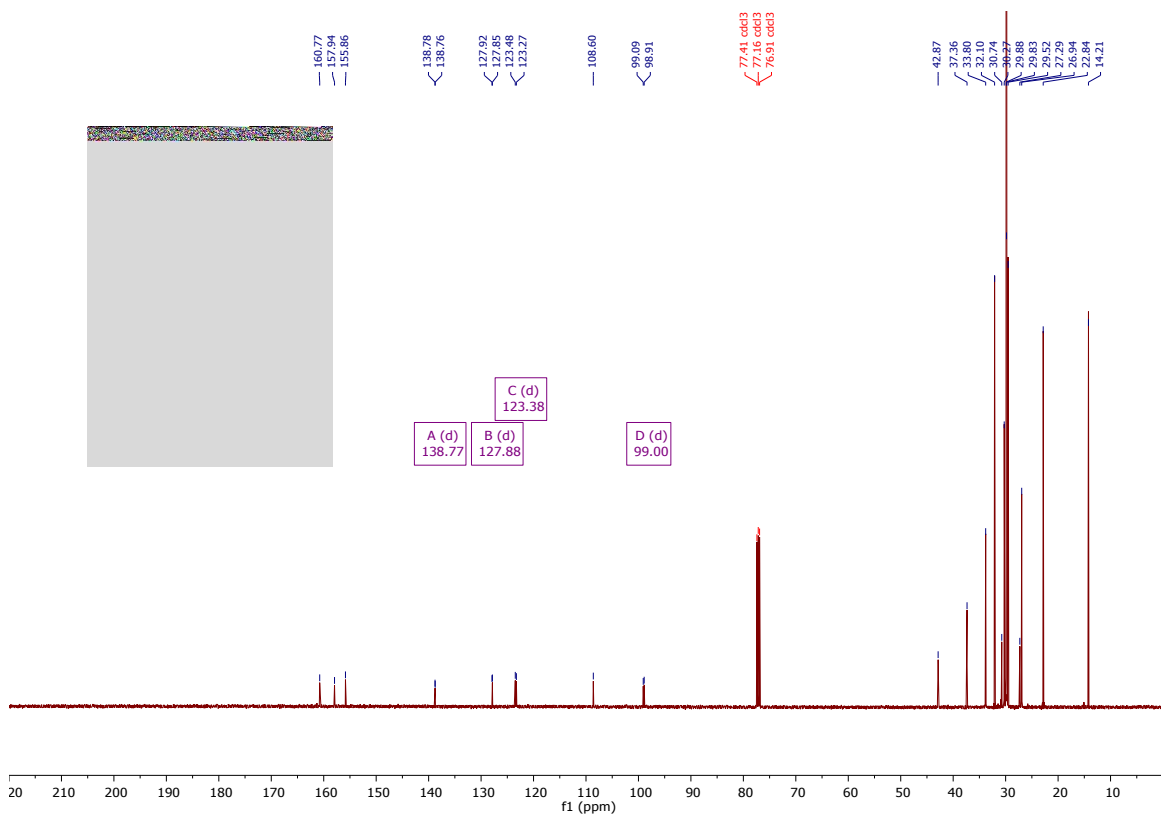
CARBON_01



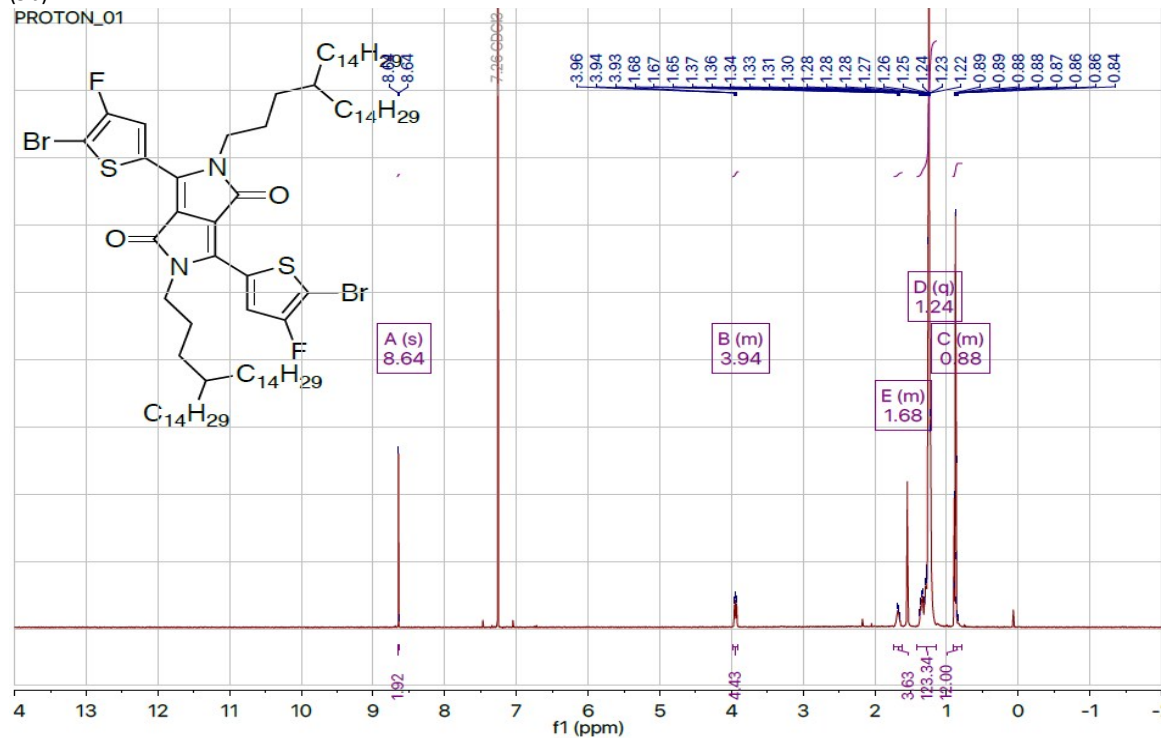
3,6-bis(5-bromo-4-fluorothiophen-2-yl)-2,5-bis(4-octadecyldocosyl)-2,5-dihydropyrrolo[3,4-c]pyrrole-1,4-dione (9a)



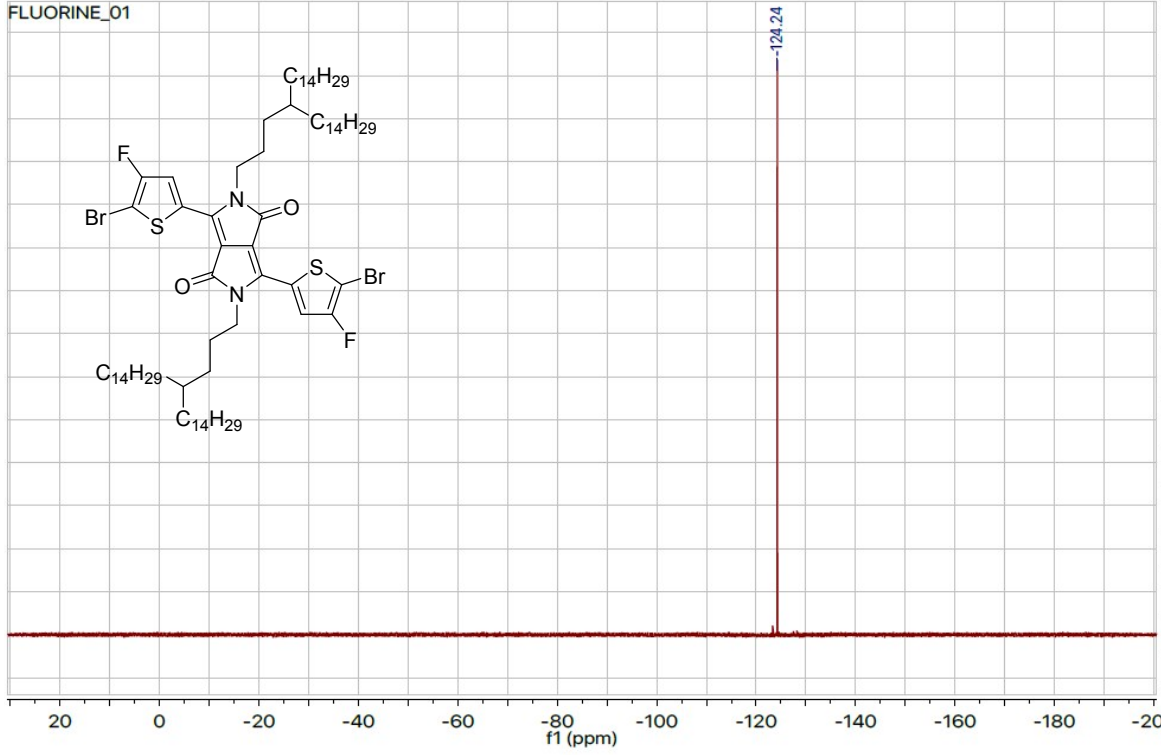




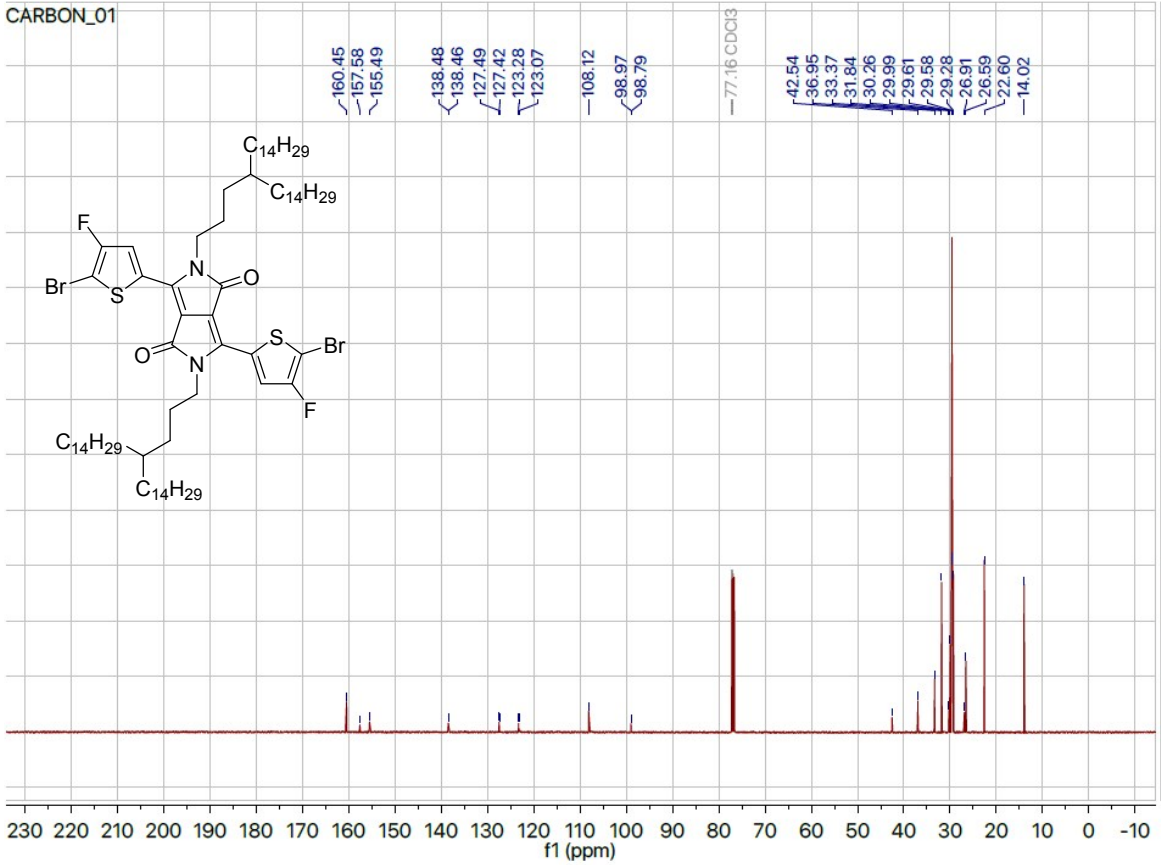
3,6-bis(5-bromo-4-fluorothiophen-2-yl)-2,5-bis(4-tetradecyloctadecyl)-2,5-dihydropyrrolo[3,4-c]pyrrole-1,4-dione
(9b)



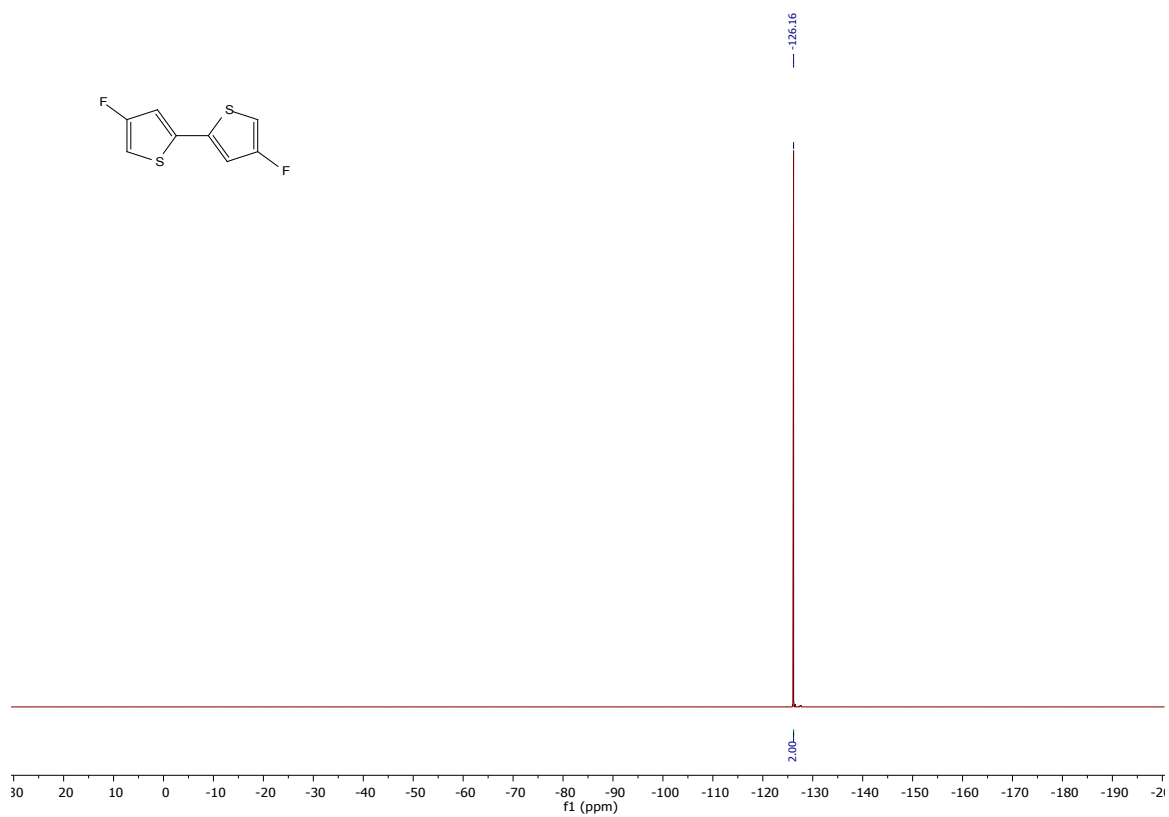
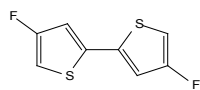
FLUORINE_01

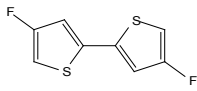


CARBON_01

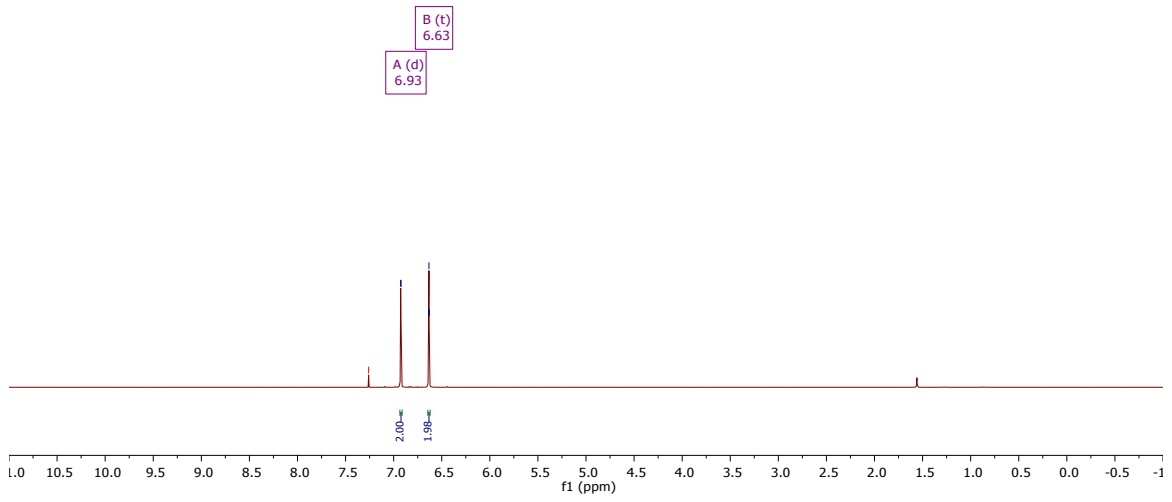


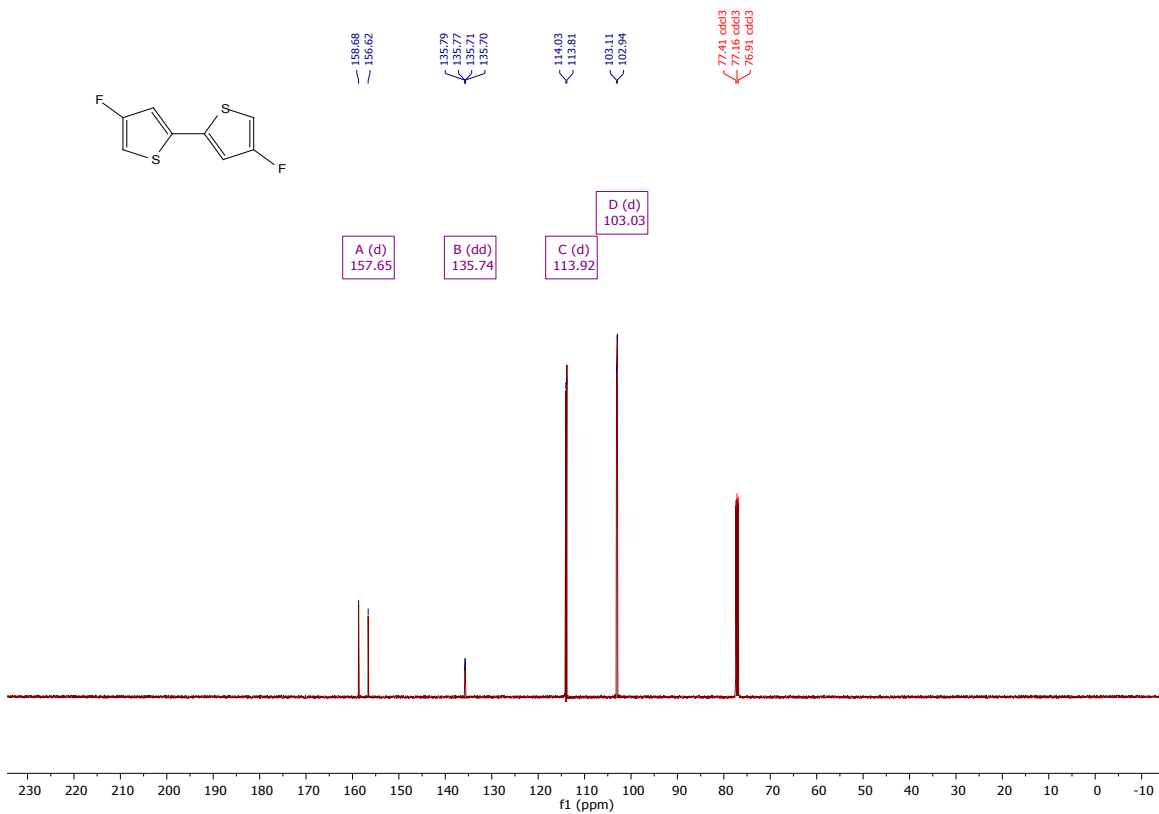
4,4'-difluoro-2,2'-bithiophene (10)



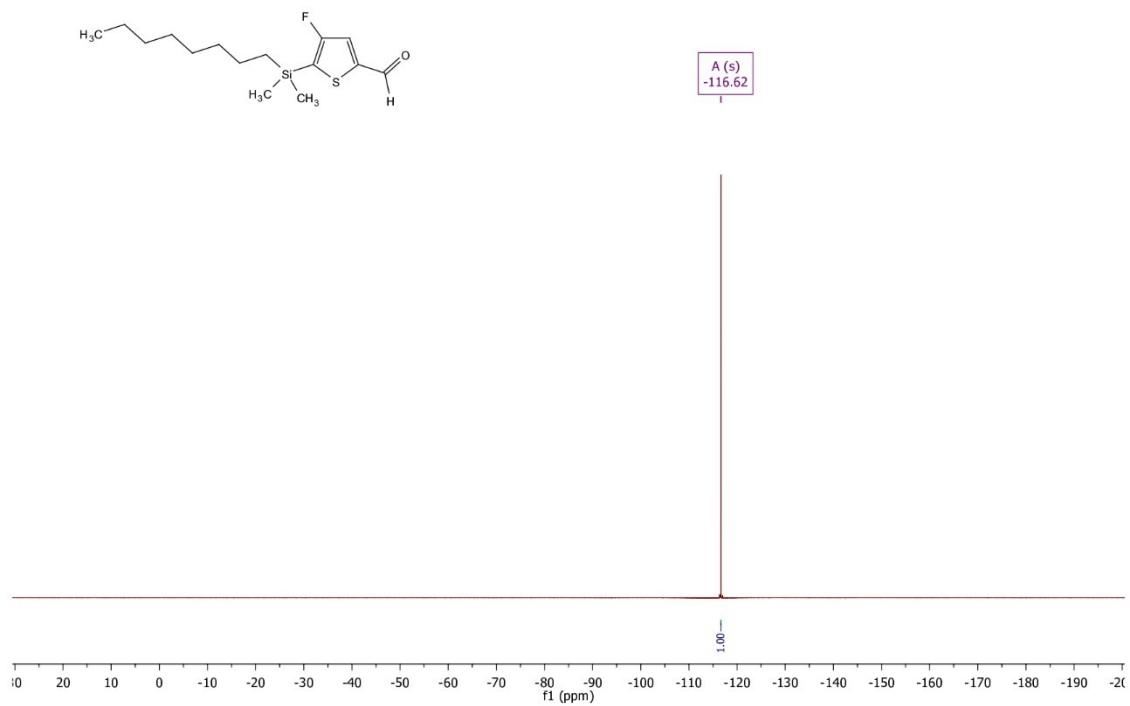


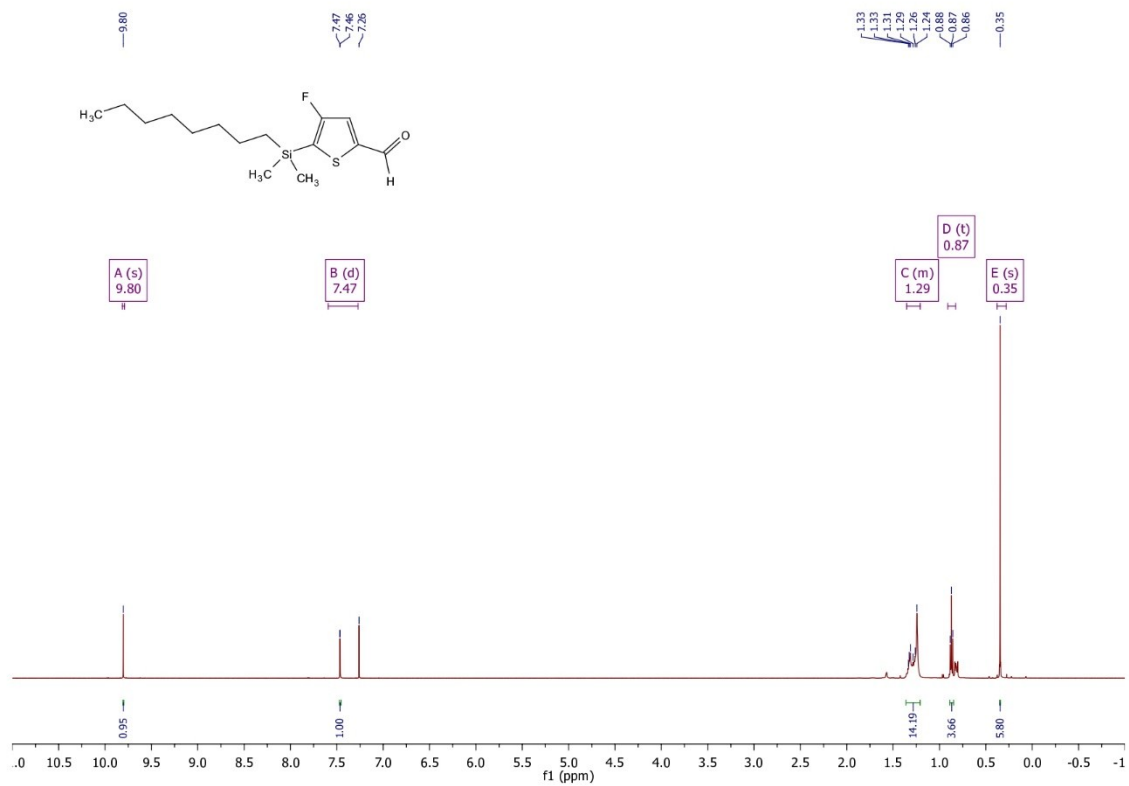
- 7.26 cd03
6.93
6.92
6.64
6.63



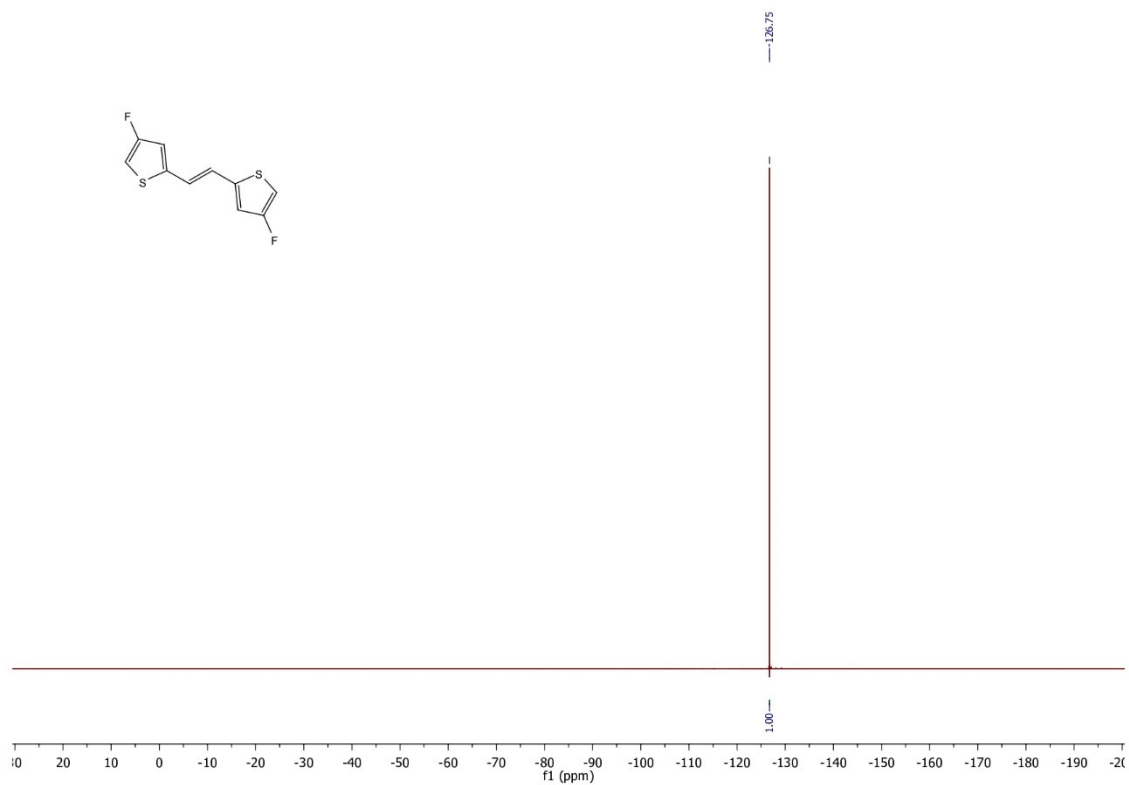


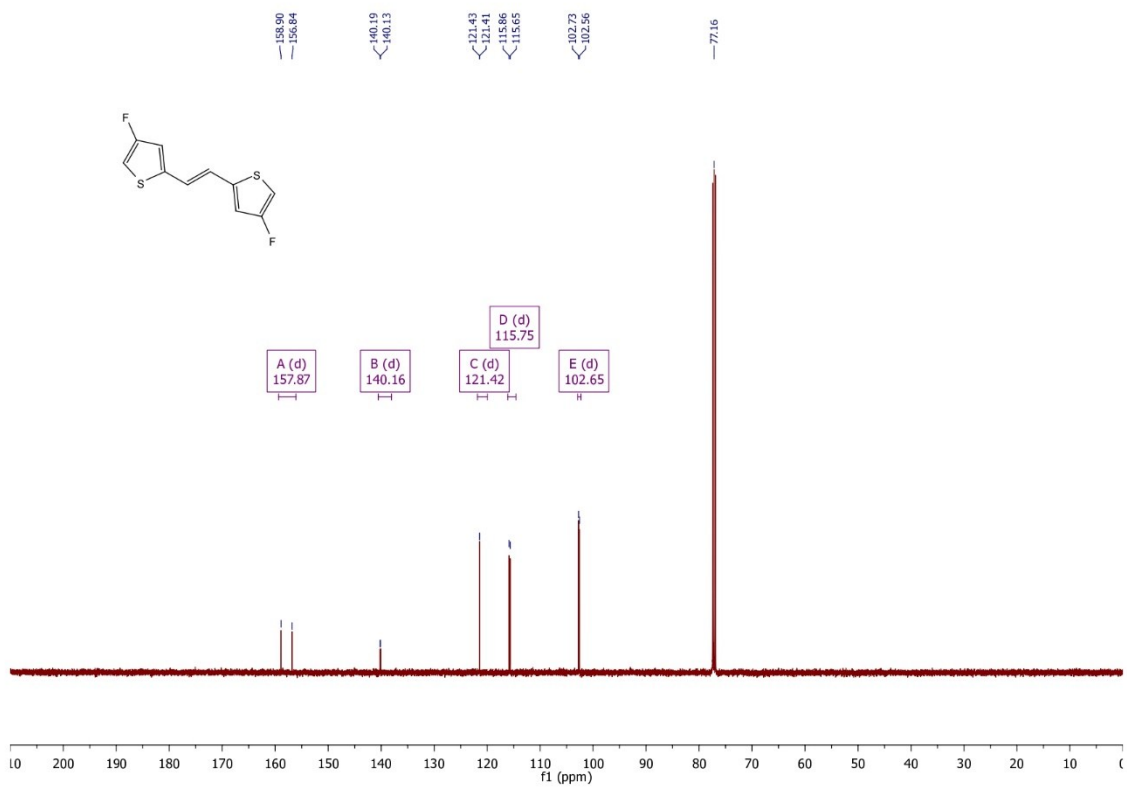
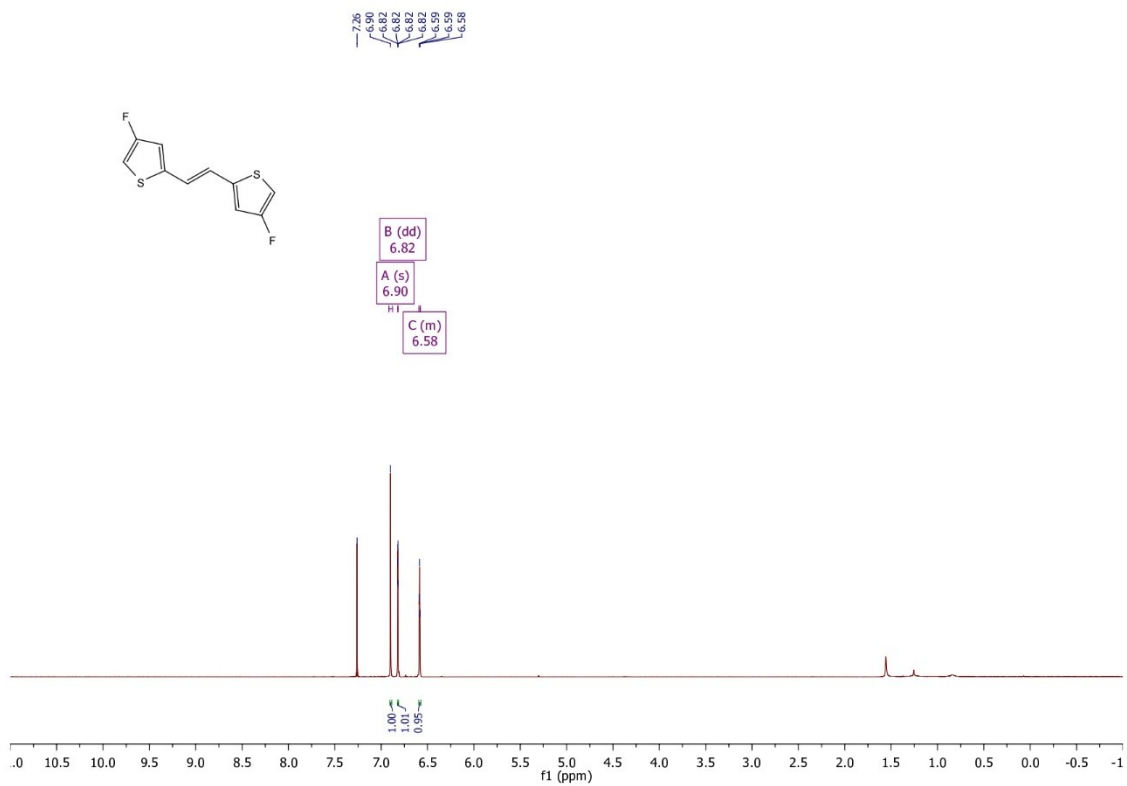
5-(dimethyl(octyl)silyl)-4-fluorothiophene-2-carbaldehyde (11)



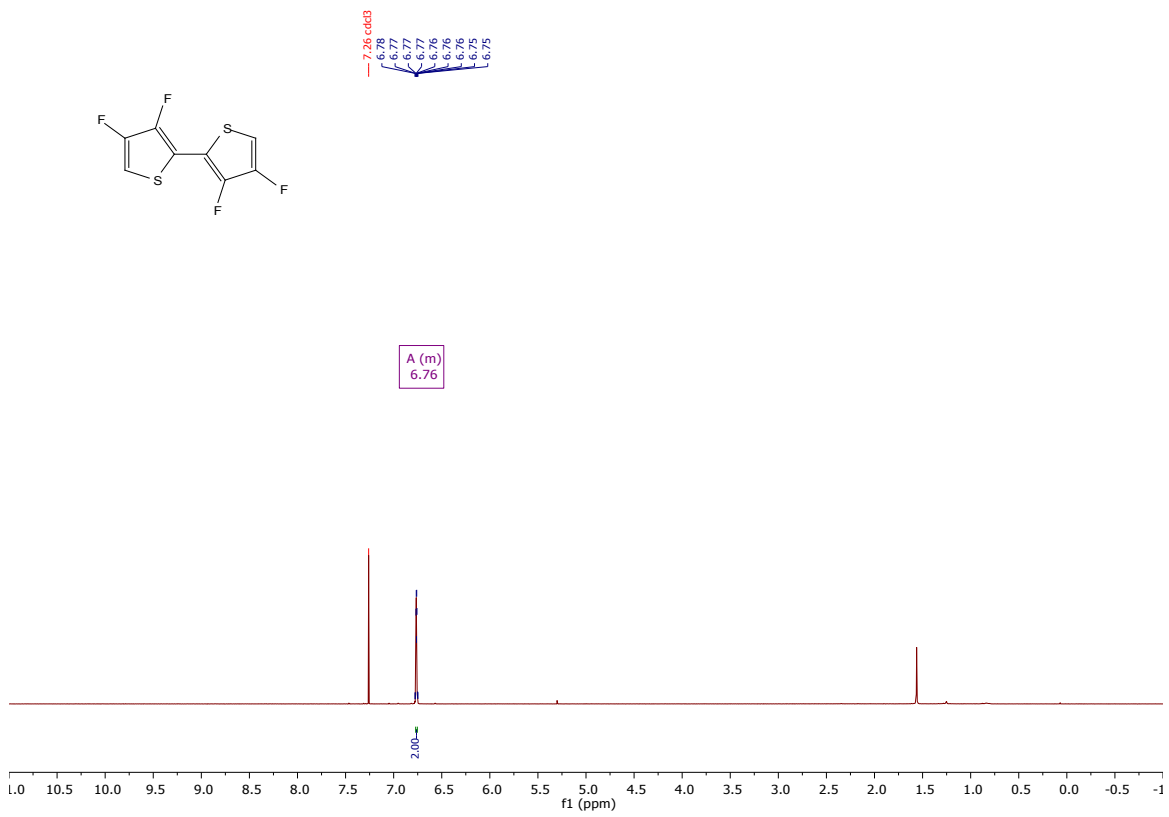


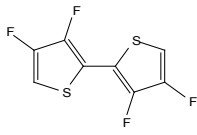
(E)-1,2-bis(4-fluorothiophen-2-yl)ethene (12)





3,3',4,4'-tetrafluoro-2,2'-bithiophene (14)





146.56
146.40
144.47
144.32
143.30
143.18
141.01
111.00
110.97
110.95
110.94
110.93
110.92
110.90
110.87
110.85
102.76
102.73
102.72
102.69
102.63
102.60
102.59
102.56

77.42 cdd3
77.16 cdd3
76.91 cdd3

